www.ti.com

MIXED SIGNAL MICROCONTROLLER

FEATURES

- Low Supply-Voltage Range: 1.8 V to 3.6 V
- Ultra-Low Power Consumption
 - Active Mode: 230 µA at 1 MHz, 2.2 V
 - Standby Mode: 0.5 μA
 - Off Mode (RAM Retention): 0.1 μA
- Five Power-Saving Modes
- Ultra-Fast Wake-Up From Standby Mode in Less Than 1 µs
- 16-Bit RISC Architecture, 62.5-ns Instruction Cycle Time
- Basic Clock Module Configurations
 - Internal Frequencies up to 16 MHz With Four Calibrated Frequency
 - Internal Very-Low-Power Low-Frequency (LF) Oscillator
 - 32-kHz Crystal
 - External Digital Clock Source
- Two 16-Bit Timer_A With Three Capture/Compare Registers
- Up to 24 Capacitive-Touch Enabled I/O Pins

- Universal Serial Communication Interface (USCI)
 - Enhanced UART Supporting Auto Baudrate Detection (LIN)
 - IrDA Encoder and Decoder
 - Synchronous SPI
 - I²C™
- 10-Bit 200-ksps Analog-to-Digital (A/D)
 Converter With Internal Reference, Sample-and-Hold, and Autoscan (See Table 1)
- Brownout Detector
- Serial Onboard Programming, No External Programming Voltage Needed, Programmable Code Protection by Security Fuse
- On-Chip Emulation Logic With Spy-Bi-Wire Interface
- Family Members are Summarized in Table 1
- Package Options
 - TSSOP: 20 Pin, 28 Pin
 - PDIP: 20 PinQFN: 32 Pin
- For Complete Module Descriptions, See the MSP430x2xx Family User's Guide (SLAU144)

DESCRIPTION

The Texas Instruments MSP430 family of ultra-low-power microcontrollers consists of several devices featuring different sets of peripherals targeted for various applications. The architecture, combined with five low-power modes, is optimized to achieve extended battery life in portable measurement applications. The device features a powerful 16-bit RISC CPU, 16-bit registers, and constant generators that contribute to maximum code efficiency. The digitally controlled oscillator (DCO) allows wake-up from low-power modes to active mode in less than 1 µs.

The MSP430G2x03 and MSP430G2x33 series are ultra-low-power mixed signal microcontrollers with built-in 16-bit timers, up to 24 I/O capacitive-touch enabled pins, and built-in communication capability using the universal serial communication interface. In addition, the MSP430G2x33 family members have a 10-bit A/D converter. For configuration details see Table 1.

Typical applications include low-cost sensor systems that capture analog signals, convert them to digital values, and then process the data for display or for transmission to a host system.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



Table 1. Available Options (1)(2)

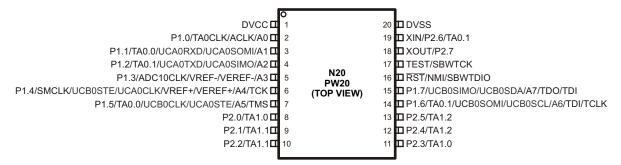
Device	BSL	EEM	Flash (KB)	RAM (B)	Timer_A	ADC10 Channel	USCI A0/B0	Clock	I/O	Package Type			
MSP430G2533IRHB32									24	32-QFN			
MSP430G2533IPW28		1	16	512	2x TA3	8	1	LF,	24	28-TSSOP			
MSP430G2533IPW20	1	1		312	2X 1A3	8	ı	DCO, VLO	16	20-TSSOP			
MSP430G2533IN20									16	20-PDIP			
MSP430G2433IRHB32									24	32-QFN			
MSP430G2433IPW28	1	1	0	512	2x TA3	0	4	LF,	24	28-TSSOP			
MSP430G2433IPW20		1	8	512	2X 1A3	8	1	DCO, VLO	16	20-TSSOP			
MSP430G2433IN20									16	20-PDIP			
MSP430G2333IRHB32									24	32-QFN			
MSP430G2333IPW28			4	050	2x TA3	0	4	LF,	24	28-TSSOP			
MSP430G2333IPW20	1	1	1	4	256	23 173	8	1	DCO, VLO	16	20-TSSOP		
MSP430G2333IN20									16	20-PDIP			
MSP430G2233IRHB32									24	32-QFN			
MSP430G2233IPW28		1	2	250	2x TA3	0	4	LF,	24	28-TSSOP			
MSP430G2233IPW20	1	1	2	256	2X 1A3	8	1	DCO, VLO	16	20-TSSOP			
MSP430G2233IN20									16	20-PDIP			
MSP430G2403IRHB32									24	32-QFN			
MSP430G2403IPW28	1	1	8	512	2x TA3		1	LF, DCO,	24	28-TSSOP			
MSP430G2403IPW20	'	'	0	312	2X 1A3	-	ı	VLO	16	20-TSSOP			
MSP430G2403IN20									16	20-PDIP			
MSP430G2303IRHB32									24	32-QFN			
MSP430G2303IPW28	1	1	4	256	2x TA3		1	LF,	24	28-TSSOP			
MSP430G2303IPW20	1	1	4	256	2X 1A3	-	1	DCO, VLO	16	20-TSSOP			
MSP430G2303IN20									16	20-PDIP			
MSP430G2203IRHB32									24	32-QFN			
MSP430G2203IPW28		_	0		0v T40			LF,	24	28-TSSOP			
MSP430G2203IPW20	1	1	1	1	2	256	2x TA3	-	1	DCO, VLO	16	20-TSSOP	
MSP430G2203IN20													

⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

⁽²⁾ Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.



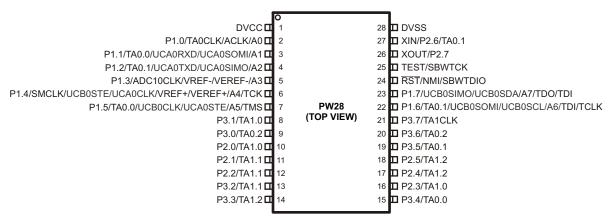
Device Pinout, MSP430G2x03 and MSP430G2x33, 20-Pin Devices, TSSOP and PDIP



NOTE: ADC10 is available on MSP430G2x33 devices only.

NOTE: The pulldown resistors of port P3 should be enabled by setting P3REN.x = 1.

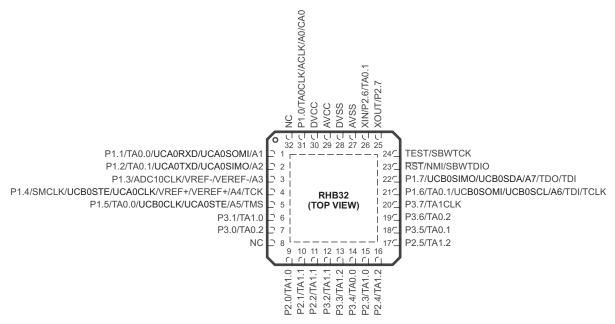
Device Pinout, MSP430G2x03 and MSP430G2x33, 28-Pin Devices, TSSOP



NOTE: ADC10 is available on MSP430G2x33 devices only.



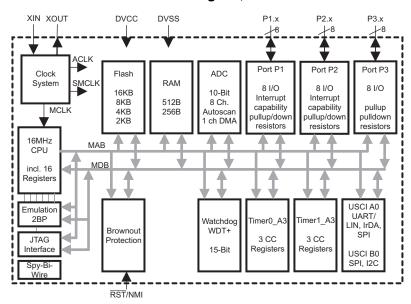
Device Pinout, MSP430G2x03 and MSP430G2x33, 32-Pin Devices, QFN



NOTE: ADC10 is available on MSP430G2x33 devices only.

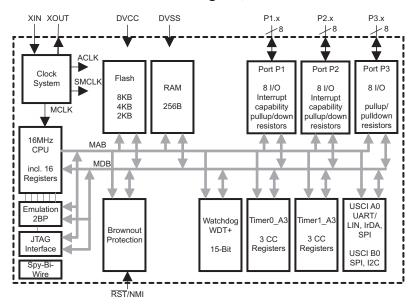


Functional Block Diagram, MSP430G2x33



NOTE: Port P3 is available on 28-pin and 32-pin devices only.

Functional Block Diagram, MSP430G2x03



NOTE: Port P3 is available on 28-pin and 32-pin devices only.



Table 2. Terminal Functions

	TERMINA				
NAME	NO.			1/0	DESCRIPTION
NAME	PW20, N20	PW28	RHB32		
P1.0/					General-purpose digital I/O pin
TA0CLK/	0	0	24	1/0	Timer0_A, clock signal TACLK input
ACLK/	2	2	31	I/O	ACLK signal output
A0					ADC10 analog input A0 ⁽¹⁾
P1.1/					General-purpose digital I/O pin
TA0.0/					Timer0_A, capture: CCI0A input, compare: Out0 output / BSL transmit
UCA0RXD/	3	3	1	I/O	USCI_A0 receive data input in UART mode
UCA0SOMI/					USCI_A0 slave data out/master in SPI mode
A1					ADC10 analog input A1 ⁽¹⁾
P1.2/					General-purpose digital I/O pin
TA0.1/					Timer0_A, capture: CCl1A input, compare: Out1 output
UCA0TXD/	4	4	2	I/O	USCI_A0 transmit data output in UART mode
UCA0SIMO/					USCI_A0 slave data in/master out in SPI mode
A2					ADC10 analog input A2 ⁽¹⁾
P1.3/					General-purpose digital I/O pin
ADC10CLK/					ADC10, conversion clock output ⁽¹⁾
A3/	5	5	3	I/O	ADC10 analog input A3 ⁽¹⁾
VREF-/VEREF-					ADC10 negative reference voltage ⁽¹⁾
P1.4/					General-purpose digital I/O pin
SMCLK/					SMCLK signal output
UCB0STE/					USCI_B0 slave transmit enable
UCA0CLK/	6	6	4	I/O	USCI_A0 clock input/output
A4/					ADC10 analog input A4 ⁽¹⁾
VREF+/VEREF+					ADC10 positive reference voltage ⁽¹⁾
тск					JTAG test clock, input terminal for device programming and test
P1.5/					General-purpose digital I/O pin
TA0.0/					Timer0_A, compare: Out0 output / BSL receive
UCB0CLK/					USCI_B0 clock input/output
UCA0STE/	7	7	5	I/O	USCI_A0 slave transmit enable
A5/					ADC10 analog input A5 ⁽¹⁾
TMS					JTAG test mode select, input terminal for device programming and test
P1.6/					General-purpose digital I/O pin
TA0.1/					Timer0_A, compare: Out1 output
A6/					ADC10 analog input A6 ⁽¹⁾
UCB0SOMI/	14	22	21	I/O	USCI_B0 slave out/master in SPI mode,
UCB0SCL/					USCI_B0 SCL I2C clock in I2C mode
TDI/TCLK					JTAG test data input or test clock input during programming and test
P1.7/					General-purpose digital I/O pin
A7/					ADC10 analog input A7 ⁽¹⁾
UCB0SIMO/					USCI_B0 slave in/master out in SPI mode
UCB0SDA/	15	23	22	I/O	USCI_B0 SDA I2C data in I2C mode
TDO/TDI					JTAG test data output terminal or test data input during programming and
150/151					test (2)

⁽¹⁾ MSP430G2x33 devices only(2) TDO or TDI is selected via JTAG instruction.



Table 2. Terminal Functions (continued)

	TERMINA	۱L			
		NO.		I/O	DESCRIPTION
NAME	PW20, N20	PW28	RHB32	1/0	DESCRIPTION
P2.0/	0	40	0	1/0	General-purpose digital I/O pin
TA1.0	8	10	9	1/0	Timer1_A, capture: CCI0A input, compare: Out0 output
P2.1/	9	11	10	1/0	General-purpose digital I/O pin
TA1.1	9	11	10	1/0	Timer1_A, capture: CCI1A input, compare: Out1 output
P2.2/	10	12	11	I/O	General-purpose digital I/O pin
TA1.1	10	12		٥	Timer1_A, capture: CCI1B input, compare: Out1 output
P2.3/	11	16	15	I/O	General-purpose digital I/O pin
TA1.0				., 0	Timer1_A, capture: CCI0B input, compare: Out0 output
P2.4/	12	17	16	I/O	General-purpose digital I/O pin
TA1.2				., 0	Timer1_A, capture: CCl2A input, compare: Out2 output
P2.5/	13	18	17	I/O	General-purpose digital I/O pin
TA1.2					Timer1_A, capture: CCl2B input, compare: Out2 output
XIN/					Input terminal of crystal oscillator
P2.6/	19	27	26	I/O	General-purpose digital I/O pin
TA0.1					Timer0_A, compare: Out1 output
XOUT/	18	26	25	I/O	Output terminal of crystal oscillator ⁽³⁾
P2.7					General-purpose digital I/O pin
P3.0/	-	9	7	I/O	General-purpose digital I/O pin
TA0.2					Timer0_A, capture: CCI2A input, compare: Out2 output
P3.1/	-	8	6	I/O	General-purpose digital I/O pin
TA1.0					Timer1_A, compare: Out0 output
P3.2/	-	13	12	I/O	General-purpose digital I/O pin
TA1.1					Timer1_A, compare: Out1 output
P3.3/ TA1.2	-	14	13	I/O	General-purpose digital I/O
P3.4/					Timer1_A, compare: Out2 output General-purpose digital I/O
TA0.0	-	15	14	I/O	Timer0_A, compare: Out0 output
P3.5/					General-purpose digital I/O
TA0.1	-	19	18	I/O	Timer0_A, compare: Out1 output
P3.6/					General-purpose digital I/O
TA0.2	-	20	19	I/O	TimerO_A, compare: Out2 output
P3.7/					General-purpose digital I/O
TA1CLK	-	21	20	I/O	Timer1_A, clock signal TACLK input
RST/					Reset
NMI/	16	24	23	ı	Nonmaskable interrupt input
SBWTDIO					Spy-Bi-Wire test data input/output during programming and test
TEST/	17	25	24	ı	Selects test mode for JTAG pins on Port 1. The device protection fuse is connected to TEST.
SBWTCK]		Spy-Bi-Wire test clock input during programming and test
AVCC	NA	NA	29	NA	Analog supply voltage
DVCC	1	1	30	NA	Digital supply voltage
DVSS	20	28	27, 28	NA	Ground reference
NC	NA	NA	8, 32	NA	Not connected

⁽³⁾ If XOUT/P2.7 is used as an input, excess current flows until P2SEL.7 is cleared. This is due to the oscillator output driver connection to this pad after reset.



Table 2. Terminal Functions (continued)

	TERMINA	\L						
	NO.			1/0	DESCRIPTION			
NAME	PW20, N20	PW28	RHB32	., 0	DEGGINI HON			
QFN Pad	NA	NA	Pad	NA	QFN package pad connection to VSS recommended.			



SHORT-FORM DESCRIPTION

CPU

The MSP430 CPU has a 16-bit RISC architecture that is highly transparent to the application. All operations, other than program-flow instructions, are performed as register operations in conjunction with seven addressing modes for source operand and four addressing modes for destination operand.

The CPU is integrated with 16 registers that provide reduced instruction execution time. The register-to-register operation execution time is one cycle of the CPU clock.

Four of the registers, R0 to R3, are dedicated as program counter, stack pointer, status register, and constant generator, respectively. The remaining registers are general-purpose registers.

Peripherals are connected to the CPU using data, address, and control buses, and can be handled with all instructions.

The instruction set consists of the original 51 instructions with three formats and seven address modes and additional instructions for the expanded address range. Each instruction can operate on word and byte data.

Instruction Set

The instruction set consists of 51 instructions with three formats and seven address modes. Each instruction can operate on word and byte data. Table 3 shows examples of the three types of instruction formats; Table 4 shows the address modes.

Program Counter	PC/R0
Stack Pointer	SP/R1
Status Register	SR/CG1/R2
Constant Generator	CG2/R3
General-Purpose Register	R4
General-Purpose Register	R5
General-Purpose Register	R6
General-Purpose Register	R7
General-Purpose Register	R8
General-Purpose Register	R9
General-Purpose Register	R10
General-Purpose Register	R11
General-Purpose Register	R12
General-Purpose Register	R13
General-Purpose Register	R14
General-Purpose Register	R15

Table 3. Instruction Word Formats

INSTRUCTION FORMAT	EXAMPLE	OPERATION
Dual operands, source-destination	ADD R4,R5	R4 + R5> R5
Single operands, destination only	CALL R8	PC>(TOS), R8> PC
Relative jump, un/conditional	JNE	Jump-on-equal bit = 0

Table 4. Address Mode Descriptions⁽¹⁾

ADDRESS MODE	S	D	SYNTAX	EXAMPLE	OPERATION
Register	✓	✓	MOV Rs,Rd	MOV R10,R11	R10> R11
Indexed	✓	✓	MOV X(Rn),Y(Rm)	MOV 2(R5),6(R6)	M(2+R5)> M(6+R6)
Symbolic (PC relative)	✓	✓	MOV EDE,TONI		M(EDE)> M(TONI)
Absolute	✓	✓	MOV &MEM,&TCDAT		M(MEM)> M(TCDAT)
Indirect	✓		MOV @Rn,Y(Rm)	MOV @R10,Tab(R6)	M(R10)> M(Tab+R6)
Indirect autoincrement	✓		MOV @Rn+,Rm	MOV @R10+,R11	M(R10)> R11 R10 + 2> R10
Immediate	✓		MOV #X,TONI	MOV #45,TONI	#45> M(TONI)

(1) S = source, D = destination



Operating Modes

The MSP430 has one active mode and five software selectable low-power modes of operation. An interrupt event can wake up the device from any of the low-power modes, service the request, and restore back to the low-power mode on return from the interrupt program.

The following six operating modes can be configured by software:

- Active mode (AM)
 - All clocks are active
- Low-power mode 0 (LPM0)
 - CPU is disabled
 - ACLK and SMCLK remain active, MCLK is disabled
- Low-power mode 1 (LPM1)
 - CPU is disabled
 - ACLK and SMCLK remain active, MCLK is disabled
 - DCO's dc generator is disabled if DCO not used in active mode
- Low-power mode 2 (LPM2)
 - CPU is disabled
 - MCLK and SMCLK are disabled
 - DCO's dc generator remains enabled
 - ACLK remains active
- Low-power mode 3 (LPM3)
 - CPU is disabled
 - MCLK and SMCLK are disabled
 - DCO's dc generator is disabled
 - ACLK remains active
- Low-power mode 4 (LPM4)
 - CPU is disabled
 - ACLK is disabled
 - MCLK and SMCLK are disabled
 - DCO's dc generator is disabled
 - Crystal oscillator is stopped



Interrupt Vector Addresses

The interrupt vectors and the power-up starting address are located in the address range 0FFFFh to 0FFC0h. The vector contains the 16-bit address of the appropriate interrupt handler instruction sequence.

If the reset vector (located at address 0FFFEh) contains 0FFFFh (for example, flash is not programmed), the CPU goes into LPM4 immediately after power-up.

Table 5. Interrupt Sources, Flags, and Vectors

INTERRUPT SOURCE	INTERRUPT FLAG	SYSTEM INTERRUPT	WORD ADDRESS	PRIORITY
Power-Up External Reset Watchdog Timer+ Flash key violation PC out-of-range ⁽¹⁾	PORIFG RSTIFG WDTIFG KEYV ⁽²⁾	Reset	0FFFEh	31, highest
NMI Oscillator fault Flash memory access violation	NMIIFG OFIFG ACCVIFG ⁽²⁾⁽³⁾	(non)-maskable (non)-maskable (non)-maskable	0FFFCh	30
Timer1_A3	TACCR0 CCIFG ⁽⁴⁾	maskable	0FFFAh	29
Timer1_A3	TACCR2 TACCR1 CCIFG, TAIFG ⁽²⁾⁽⁴⁾	maskable	0FFF8h	28
			0FFF6h	27
Watchdog Timer+	WDTIFG	maskable	0FFF4h	26
Timer0_A3	TACCR0 CCIFG ⁽⁴⁾	maskable	0FFF2h	25
Timer0_A3	TACCR2 TACCR1 CCIFG, TAIFG	maskable	0FFF0h	24
USCI_A0, USCI_B0 receive USCI_B0 I2C status	UCA0RXIFG, UCB0RXIFG ⁽²⁾⁽⁵⁾	maskable	0FFEEh	23
USCI_A0, USCI_B0 transmit USCI_B0 I2C receive or transmit	UCA0TXIFG, UCB0TXIFG (2) (6)	maskable	0FFECh	22
ADC10 (MSP430G2x33 only)	ADC10IFG ⁽⁴⁾	maskable	0FFEAh	21
			0FFE8h	20
I/O Port P2 (up to eight flags)	P2IFG.0 to P2IFG.7 ⁽²⁾⁽⁴⁾	maskable	0FFE6h	19
I/O Port P1 (up to eight flags)	P1IFG.0 to P1IFG.7 ⁽²⁾⁽⁴⁾	maskable	0FFE4h	18
			0FFE2h	17
			0FFE0h	16
See ⁽⁷⁾			0FFDEh	15
See ⁽⁸⁾			0FFDEh to 0FFC0h	14 to 0, lowest

A reset is generated if the CPU tries to fetch instructions from within the module register memory address range (0h to 01FFh) or from within unused address ranges.

⁽²⁾ Multiple source flags

^{(3) (}non)-maskable: the individual interrupt-enable bit can disable an interrupt event, but the general interrupt enable cannot.

⁽⁴⁾ Interrupt flags are located in the module.

⁽⁵⁾ In SPI mode: UCBORXIFG. In I2C mode: UCALIFG, UCNACKIFG, ICSTTIFG, UCSTPIFG.

⁽⁶⁾ In UART/SPI mode: UCB0TXIFG. In I2C mode: UCB0RXIFG, UCB0TXIFG.

⁽⁷⁾ This location is used as bootstrap loader security key (BSLSKEY). A 0xAA55 at this location disables the BSL completely. A zero (0h) disables the erasure of the flash if an invalid password is supplied.

⁽⁸⁾ The interrupt vectors at addresses 0FFDEh to 0FFC0h are not used in this device and can be used for regular program code if necessary.



Special Function Registers (SFRs)

Most interrupt and module enable bits are collected into the lowest address space. Special function register bits not allocated to a functional purpose are not physically present in the device. Simple software access is provided with this arrangement.

Legend rw: Bit can be read and written.

rw-0,1: Bit can be read and written. It is reset or set by PUC.rw-(0,1): Bit can be read and written. It is reset or set by POR.

SFR bit is not present in device.

Table 6. Interrupt Enable Register 1 and 2

Address	7	6	5	4	3	2	1	0			
00h			ACCVIE	NMIIE			OFIE	WDTIE			
			rw-0	rw-0			rw-0	rw-0			
WDTIE		Watchdog Timer interrupt enable. Inactive if watchdog mode is selected. Active if Watchdog Timer is configured in interval timer mode.									
OFIE	Oscillator	fault interrupt e	enable								
NMIIE	(Non)mas	(Non)maskable interrupt enable									
ACCVIE	Flash acc	cess violation in	terrupt enable								

Address 7 6 5 4 3 2 0 01h **UCB0TXIE UCBORXIE UCA0TXIE UCA0RXIE** rw-0 rw-0 rw-0

UCA0RXIE USCI_A0 receive interrupt enable
UCA0TXIE USCI_A0 transmit interrupt enable
UCB0RXIE USCI_B0 receive interrupt enable
UCB0TXIE USCI_B0 transmit interrupt enable

Table 7. Interrupt Flag Register 1 and 2

Address	7	6	5	4	3	2	1	0
02h				NMIIFG	RSTIFG	PORIFG	OFIFG	WDTIFG
				rw-0	rw-(0)	rw-(1)	rw-1	rw-(0)

WDTIFG Set on watchdog timer overflow (in watchdog mode) or security key violation.

Reset on V_{CC} power-on or a reset condition at the RST/NMI pin in reset mode.

OFIFG Flag set on oscillator fault.

PORIFG Power-On Reset interrupt flag. Set on V_{CC} power-up.

RSTIFG External reset interrupt flag. Set on a reset condition at RST/NMI pin in reset mode. Reset on V_{CC} power-up.

NMIIFG Set via RST/NMI pin

Address	7	6	5	4	3	2	1	0
03h					UCB0TXIFG	UCB0RXIFG	UCA0TXIFG	UCA0RXIFG
					nu 1	nu O	nu 1	rw O

UCA0RXIFG USCI_A0 receive interrupt flag
UCA0TXIFG USCI_A0 transmit interrupt flag
UCB0RXIFG USCI_B0 receive interrupt flag
UCB0TXIFG USCI_B0 transmit interrupt flag



Memory Organization

Table 8. Memory Organization

		MSP430G2233 MSP430G2203	MSP430G2333 MSP430G2303	MSP430G2433 MSP430G2403	MSP430G2533
Memory	Size	2kB	4kB	8kB	16kB
Main: interrupt vector	Flash	0xFFFF to 0xFFC0	0xFFFF to 0xFFC0	0xFFFF to 0xFFC0	0xFFFF to 0xFFC0
Main: code memory	Flash	0xFFFF to 0xF800	0xFFFF to 0xF000	0xFFFF to 0xE000	0xFFFF to 0xC000
Information memory	Size	256 Byte	256 Byte	256 Byte	256 Byte
	Flash	010FFh to 01000h	010FFh to 01000h	010FFh to 01000h	010FFh to 01000h
RAM	Size	256 Byte	256 Byte	512 Byte	512 Byte
		0x02FF to 0x0200	0x02FF to 0x0200	0x03FF to 0x0200	0x03FF to 0x0200
Peripherals	16-bit	01FFh to 0100h	01FFh to 0100h	01FFh to 0100h	01FFh to 0100h
	8-bit	0FFh to 010h	0FFh to 010h	0FFh to 010h	0FFh to 010h
	8-bit SFR	0Fh to 00h	0Fh to 00h	0Fh to 00h	0Fh to 00h

Bootstrap Loader (BSL)

The MSP430 BSL enables users to program the flash memory or RAM using a UART serial interface. Access to the MSP430 memory via the BSL is protected by user-defined password. For complete description of the features of the BSL and its implementation, see the *MSP430 Programming Via the Bootstrap Loader User's Guide* (SLAU319).

Table 9. BSL Function Pins

BSL FUNCTION	20-PIN PW PACKAGE 20-PIN N PACKAGE	28-PIN PACKAGE PW	32-PIN PACKAGE RHB
Data transmit	3 - P1.1	3 - P1.1	1 - P1.1
Data receive	7 - P1.5	7 - P1.5	5 - P1.5

Flash Memory

The flash memory can be programmed via the Spy-Bi-Wire/JTAG port or in-system by the CPU. The CPU can perform single-byte and single-word writes to the flash memory. Features of the flash memory include:

- Flash memory has n segments of main memory and four segments of information memory (A to D) of 64 bytes each. Each segment in main memory is 512 bytes in size.
- · Segments 0 to n may be erased in one step, or each segment may be individually erased.
- Segments A to D can be erased individually or as a group with segments 0 to n. Segments A to D are also called *information memory*.
- Segment A contains calibration data. After reset segment A is protected against programming and erasing. It
 can be unlocked but care should be taken not to erase this segment if the device-specific calibration data is
 required.



Peripherals

Peripherals are connected to the CPU through data, address, and control buses and can be handled using all instructions. For complete module descriptions, see the MSP430x2xx Family User's Guide (SLAU144).

Oscillator and System Clock

The clock system is supported by the basic clock module that includes support for a 32768-Hz watch crystal oscillator, an internal very-low-power low-frequency oscillator and an internal digitally controlled oscillator (DCO). The basic clock module is designed to meet the requirements of both low system cost and low power consumption. The internal DCO provides a fast turn-on clock source and stabilizes in less than 1 µs. The basic clock module provides the following clock signals:

- Auxiliary clock (ACLK), sourced either from a 32768-Hz watch crystal or the internal LF oscillator.
- · Main clock (MCLK), the system clock used by the CPU.
- Sub-Main clock (SMCLK), the sub-system clock used by the peripheral modules.

The DCO settings to calibrate the DCO output frequency are stored in the information memory segment A.

Calibration Data Stored in Information Memory Segment A

Calibration data is stored for both the DCO and for ADC10 organized in a tag-length-value structure.

Table 10. Tags Used by the ADC Calibration Tags

NAME	ADDRESS	VALUE	DESCRIPTION
TAG_DCO_30	0x10F6	0x01	DCO frequency calibration at $V_{CC} = 3 \text{ V}$ and $T_A = 30^{\circ}\text{C}$ at calibration
TAG_ADC10_1	0x10DA	0x10	ADC10_1 calibration tag
TAG_EMPTY	-	0xFE	Identifier for empty memory areas

Table 11. Labels Used by the ADC Calibration Tags

LABEL	ADDRESS OFFSET	SIZE	CONDITION AT CALIBRATION / DESCRIPTION
CAL_ADC_25T85	0x0010	word	INCHx = 0x1010, REF2_5 = 1, T _A = 85°C
CAL_ADC_25T30	0x000E	word	INCHx = 0x1010, REF2_5 = 1, T _A = 30°C
CAL_ADC_25VREF_FACTOR	0x000C	word	REF2_5 = 1, T _A = 30°C, I _{VREF+} = 1 mA
CAL_ADC_15T85	0x000A	word	INCHx = 0x1010, REF2_5 = 0, T _A = 85°C
CAL_ADC_15T30	0x0008	word	INCHx = 0x1010, REF2_5 = 0, T _A = 30°C
CAL_ADC_15VREF_FACTOR	0x0006	word	REF2_5 = 0, $T_A = 30^{\circ}\text{C}$, $I_{VREF+} = 0.5 \text{ mA}$
CAL_ADC_OFFSET	0x0004	word	External VREF = 1.5 V, f _{ADC10CLK} = 5 MHz
CAL_ADC_GAIN_FACTOR	0x0002	word	External VREF = 1.5 V, f _{ADC10CLK} = 5 MHz
CAL_BC1_1MHZ	0x0009	byte	-
CAL_DCO_1MHZ	0x0008	byte	-
CAL_BC1_8MHZ	0x0007	byte	-
CAL_DCO_8MHZ	0x0006	byte	-
CAL_BC1_12MHZ	0x0005	byte	-
CAL_DCO_12MHZ	0x0004	byte	-
CAL_BC1_16MHZ	0x0003	byte	-
CAL_DCO_16MHZ	0x0002	byte	-

Brownout

The brownout circuit is implemented to provide the proper internal reset signal to the device during power on and power off.



Digital I/O

Up to three 8-bit I/O ports are implemented:

- All individual I/O bits are independently programmable.
- Any combination of input, output, and interrupt condition (port P1 and port P2 only) is possible.
- Edge-selectable interrupt input capability for all bits of port P1 and port P2 (if available).
- Read/write access to port-control registers is supported by all instructions.
- Each I/O has an individually programmable pullup/pulldown resistor.
- Each I/O has an individually programmable pin oscillator enable bit to enable low-cost capacitive touch detection.

WDT+ Watchdog Timer

The primary function of the watchdog timer (WDT+) module is to perform a controlled system restart after a software problem occurs. If the selected time interval expires, a system reset is generated. If the watchdog function is not needed in an application, the module can be disabled or configured as an interval timer and can generate interrupts at selected time intervals.

Timer_A3 (TA0, TA1)

Timer0_A3 and Timer1_A3 are 16-bit timers/counters with three capture/compare registers. Timer_A3 can support multiple capture/compares, PWM outputs, and interval timing. Timer_A3 also has extensive interrupt capabilities. Interrupts may be generated from the counter on overflow conditions and from each of the capture/compare registers.

Table 12. Timer0 A3 Signal Connections

INP	UT PIN NUME	BER	DEVICE	MODULE	MODULE	MODULE	OUTPUT PIN NUMBER		IBER	
PW20, N20	PW28	RHB32	INPUT SIGNAL	INPUT NAME	BLOCK	OUTPUT SIGNAL	PW20, N20	PW28	RHB32	
P1.0-2	P1.0-2	P1.0-31	TACLK	TACLK						
			ACLK	ACLK	T:	NIA				
			SMCLK	SMCLK	Timer	NA				
PinOsc	PinOsc	PinOsc	TACLK	INCLK						
P1.1-3	P1.1-3	P1.1-1	TA0.0	CCI0A			P1.1-3	P1.1-3	P1.1-1	
			ACLK	CCI0B	CODO T/	CCDO	T40	P1.5-7	P1.5-7	P1.5-5
			V _{SS}	GND	CCR0	TA0	-	P3.4-15	P3.4-14	
			V _{CC}	V _{CC}						
P1.2-4	P1.2-4	P1.2-2	TA0.1	CCI1A			P1.2-4	P1.2-4	P1.2-2	
			CAOUT	CCI1B	0004		P1.6-14	P1.6-22	P1.6-21	
			V _{SS}	GND	CCR1	CCRT	TA1	P2.6-19	P2.6-27	P2.6-26
			V _{CC}	V _{CC}			-	P3.5-19	P3.5-18	
-	P3.0-9	P3.0-7	TA0.2	CCI2A			-	P3.0-9	P3.0-7	
PinOsc	PinOsc	PinOsc	TA0.2	CCI2B	CCDO	TA 2	-	P3.6-20	P3.6-19	
			V _{SS}	GND	CCR2	TA2				
			V _{CC}	V _{CC}						



Table 13. Timer1_A3 Signal Connections

INP	JT PIN NUME	BER	DEVICE	MODULE	MODULE	MODULE	OUTI	OUTPUT PIN NUMBER	
PW20, N20	PW28	RHB32	INPUT SIGNAL	INPUT NAME	BLOCK	OUTPUT SIGNAL	PW20, N20	PW28	RHB32
-	P3.7-21	P3.7-20	TACLK	TACLK					
			ACLK	ACLK	Timer	NIA			
			SMCLK	SMCLK	Timer	NA			
-	P3.7-21	P3.7-20	TACLK	INCLK					
P2.0-8	P2.0-10	P2.0-9	TA1.0	CCI0A			P2.0-8	P2.0-10	P2.0-9
P2.3-11	P2.3-16	P2.3-12	TA1.0	CCI0B	CCDO	TA0	P2.3-11	P2.3-16	P2.3-15
			V _{SS}	GND	CCR0			P3.1-8	P3.1-6
			V _{CC}	V _{CC}					
P2.1-9	P2.1-11	P2.1-10	TA1.1	CCI1A			P2.1-9	P2.1-11	P2.1-10
P2.2-10	P2.2-12	P2.2-11	TA1.1	CCI1B	0004		P2.2-10	P2.2-12	P2.2-11
			V _{SS}	GND	CCR1	TA1		P3.2-13	P3.2-12
			V _{CC}	V _{CC}					
P2.4-12	P2.4-17	P2.4-16	TA1.2	CCI2A			P2.4-12	P2.4-17	P2.4-16
P2.5-13	P2.5-18	P2.5-17	TA1.2	CCI2B	CCR2	T40	P2.5-13	P2.5-18	P2.5-17
			V _{SS}	GND		TA2		P3.3-14	P3.3-13
			V _{CC}	V _{CC}					

Universal Serial Communications Interface (USCI)

The USCI module is used for serial data communication. The USCI module supports synchronous communication protocols such as SPI (3 or 4 pin) and I2C, and asynchronous communication protocols such as UART, enhanced UART with automatic baudrate detection (LIN), and IrDA. Not all packages support the USCI functionality.

USCI_A0 provides support for SPI (3 or 4 pin), UART, enhanced UART, and IrDA.

USCI_B0 provides support for SPI (3 or 4 pin) and I2C.

ADC10 (MSP430G2x33 Only)

The ADC10 module supports fast 10-bit analog-to-digital conversions. The module implements a 10-bit SAR core, sample select control, reference generator, and data transfer controller (DTC) for automatic conversion result handling, allowing ADC samples to be converted and stored without any CPU intervention.



Peripheral File Map

Table 14. Peripherals With Word Access

MODULE	REGISTER DESCRIPTION	REGISTER NAME	OFFSET
ADC10	ADC data transfer start address	ADC10SA	1BCh
(MSP430G2x33 devices only)	ADC memory	ADC10MEM	1B4h
	ADC control register 1	ADC10CTL1	1B2h
	ADC control register 0	ADC10CTL0	1B0h
Timer1_A3	Capture/compare register	TA1CCR2	0196h
	Capture/compare register	TA1CCR1	0194h
	Capture/compare register	TA1CCR0	0192h
	Timer_A register	TA1R	0190h
	Capture/compare control	TA1CCTL2	0186h
	Capture/compare control	TA1CCTL1	0184h
	Capture/compare control	TA1CCTL0	0182h
	Timer_A control	TA1CTL	0180h
	Timer_A interrupt vector	TA1IV	011Eh
Timer0_A3	Capture/compare register	TA0CCR2	0176h
	Capture/compare register	TA0CCR1	0174h
	Capture/compare register	TA0CCR0	0172h
	Timer_A register	TA0R	0170h
mer0_A3	Capture/compare control	TA0CCTL2	0166h
	Capture/compare control	TA0CCTL1	0164h
	Capture/compare control	TA0CCTL0	0162h
	Timer_A control	TA0CTL	0160h
	Timer_A interrupt vector	TAOIV	012Eh
Flash Memory	Flash control 3	FCTL3	012Ch
	Flash control 2	FCTL2	012Ah
	Flash control 1	FCTL1	0128h
Watchdog Timer+	Watchdog/timer control	WDTCTL	0120h

Table 15. Peripherals With Byte Access

MODULE	REGISTER DESCRIPTION	REGISTER NAME	OFFSET
USCI_B0	USCI_B0 transmit buffer	UCB0TXBUF	06Fh
	USCI_B0 receive buffer	UCB0RXBUF	06Eh
	USCI_B0 status	UCB0STAT	06Dh
	USCI B0 I2C Interrupt enable	UCB0CIE	06Ch
	USCI_B0 bit rate control 1	UCB0BR1	06Bh
	USCI_B0 bit rate control 0	UCB0BR0	06Ah
	USCI_B0 control 1	UCB0CTL1	069h
	USCI_B0 control 0	UCB0CTL0	068h
	USCI_B0 I2C slave address	UCB0SA	011Ah
	USCI_B0 I2C own address	UCB0OA	0118h



Table 15. Peripherals With Byte Access (continued)

MODULE	REGISTER DESCRIPTION	REGISTER NAME	OFFSET
USCI_A0	USCI_A0 transmit buffer	UCA0TXBUF	067h
	USCI_A0 receive buffer	UCA0RXBUF	066h
	USCI_A0 status	UCA0STAT	065h
	USCI_A0 modulation control	UCA0MCTL	064h
	USCI_A0 baud rate control 1	UCA0BR1	063h
	USCI_A0 baud rate control 0	UCA0BR0	062h
	USCI_A0 control 1	UCA0CTL1	061h
	USCI_A0 control 0	UCA0CTL0	060h
	USCI_A0 IrDA receive control	UCA0IRRCTL	05Fh
	USCI_A0 IrDA transmit control	UCA0IRTCTL	05Eh
	USCI_A0 auto baud rate control	UCA0ABCTL	05Dh
ADC10	ADC analog enable 0	ADC10AE0	04Ah
(MSP430G2x33 devices only)	ADC analog enable 1	ADC10AE1	04Bh
asic Clock System+	ADC data transfer control register 1	ADC10DTC1	049h
	ADC data transfer control register 0	ADC10DTC0	048h
Basic Clock System+	Basic clock system control 3	BCSCTL3	053h
	Basic clock system control 2	BCSCTL2	058h
	Basic clock system control 1	BCSCTL1	057h
	DCO clock frequency control	DCOCTL	056h
Port P3	Port P3 selection 2. pin	P3SEL2	043h
(28-pin PW and 32-pin RHB only)	Port P3 resistor enable	P3REN	010h
	Port P3 selection	P3SEL	01Bh
	Port P3 direction	P3DIR	01Ah
	Port P3 output	P3OUT	019h
	Port P3 input	P3IN	018h
Port P2	Port P2 selection 2	P2SEL2	042h
	Port P2 resistor enable	P2REN	02Fh
	Port P2 selection	P2SEL	02Eh
	Port P2 interrupt enable	P2IE	02Dh
	Port P2 interrupt edge select	P2IES	02Ch
	Port P2 interrupt flag	P2IFG	02Bh
	Port P2 direction	P2DIR	02Ah
	Port P2 output	P2OUT	029h
	Port P2 input	P2IN	028h
Port P1	Port P1 selection 2	P1SEL2	041h
	Port P1 resistor enable	P1REN	027h
	Port P1 selection	P1SEL	026h
	Port P1 interrupt enable	P1IE	025h
	Port P1 interrupt edge select	P1IES	024h
	Port P1 interrupt flag	P1IFG	023h
	Port P1 direction	P1DIR	022h
	Port P1 output	P1OUT	021h
	Port P1 input	P1IN	020h
Special Function	SFR interrupt flag 2	IFG2	003h
•	SFR interrupt flag 1	IFG1	002h
	SFR interrupt enable 2	IE2	001h
	SFR interrupt enable 1	IE1	000h

www.ti.com

Absolute Maximum Ratings⁽¹⁾

Voltage applied at V _{CC} to V _{SS}	-0.3 V to 4.1 V	
Voltage applied to any pin ⁽²⁾	-0.3 V to V _{CC} + 0.3 V	
Diode current at any device pin	±2 mA	
- (3)	Unprogrammed device	−55°C to 150°C
Storage temperature range, T _{stg} ⁽³⁾	Programmed device	−55°C to 150°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages referenced to V_{SS}. The JTAG fuse-blow voltage, V_{FB}, is allowed to exceed the absolute maximum rating. The voltage is applied to the TEST pin when blowing the JTAG fuse.
- (3) Higher temperature may be applied during board soldering according to the current JEDEC J-STD-020 specification with peak reflow temperatures not higher than classified on the device label on the shipping boxes or reels.

Recommended Operating Conditions

Typical values are specified at $V_{CC} = 3.3 \text{ V}$ and $T_A = 25^{\circ}\text{C}$ (unless otherwise noted)

			MIN	NOM	MAX	UNIT
		During program execution	1.8		3.6	
V _{CC}	Supply voltage	During flash programming and erase	2.2		3.6	V
V _{SS}	Supply voltage					V
T _A	Operating free-air temperature		-40		85	°C
	Processor frequency (maximum MCLK frequency using the USART module) $^{(1)(2)}$	V _{CC} = 1.8 V, Duty cycle = 50% ± 10%	dc		6	
f _{SYSTEM}		V _{CC} = 2.7 V, Duty cycle = 50% ± 10%	dc		12	MHz
		V _{CC} = 3.3 V, Duty cycle = 50% ± 10%	dc		16	

- (1) The MSP430 CPU is clocked directly with MCLK. Both the high and low phase of MCLK must not exceed the pulse width of the specified maximum frequency.
- (2) Modules might have a different maximum input clock specification. See the specification of the respective module in this data sheet.



Note: Minimum processor frequency is defined by system clock. Flash program or erase operations require a minimum V_{CC} of 2.2 V.

Figure 1. Safe Operating Area



Electrical Characteristics

Active Mode Supply Current Into V_{CC} Excluding External Current

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (1)(2)

PARA	METER	TEST CONDITIONS	T _A	V _{CC}	MIN TYP	MAX	UNIT
	$f_{DCO} = f_{MCLK} = f_{SMCLK} = 1 \text{ MHz},$		2.2 V	230			
	tive mode (AM) rrent at 1 MHz	f _{ACLK} = 0 Hz, Program executes in flash, BCSCTL1 = CALBC1_1MHZ, DCOCTL = CALDCO_1MHZ, CPUOFF = 0, SCG0 = 0, SCG1 = 0, OSCOFF = 0		3 V	330	420	μΑ

- All inputs are tied to 0 V or to V_{CC} . Outputs do not source or sink any current. The currents are characterized with a Micro Crystal CC4V-T1A SMD crystal with a load capacitance of 9 pF. The internal and external load capacitance is chosen to closely match the required 9 pF.

Typical Characteristics, Active Mode Supply Current (Into V_{cc})

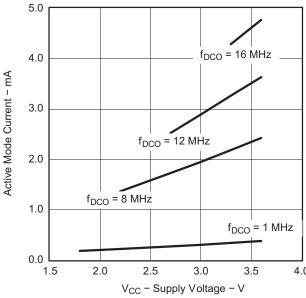


Figure 2. Active Mode Current vs V_{CC} , $T_A = 25$ °C

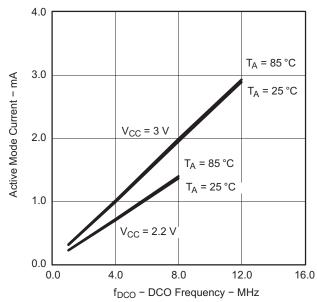


Figure 3. Active Mode Current vs DCO Frequency



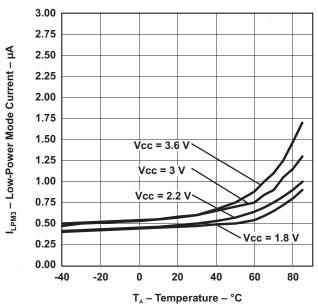
Low-Power Mode Supply Currents (Into V_{CC}) Excluding External Current

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (1) (2)

P	ARAMETER	TEST CONDITIONS	T _A	V _{cc}	MIN TYP	MAX	UNIT
I _{LPM0,1MHz}	Low-power mode 0 (LPM0) current ⁽³⁾	$ \begin{aligned} f_{\text{MCLK}} &= 0 \text{ MHz,} \\ f_{\text{SMCLK}} &= f_{\text{DCO}} = 1 \text{ MHz,} \\ f_{\text{ACLK}} &= 32768 \text{ Hz,} \\ \text{BCSCTL1} &= \text{CALBC1_1MHZ,} \\ \text{DCOCTL} &= \text{CALDCO_1MHZ,} \\ \text{CPUOFF} &= 1, \text{SCG0} = 0, \text{SCG1} = 0, \\ \text{OSCOFF} &= 0 \end{aligned} $	25°C	2.2 V	56		μΑ
I _{LPM2}	Low-power mode 2 (LPM2) current ⁽⁴⁾	$\begin{split} f_{\text{MCLK}} &= f_{\text{SMCLK}} = 0 \text{ MHz}, \\ f_{\text{DCO}} &= 1 \text{ MHz}, \\ f_{\text{ACLK}} &= 32768 \text{ Hz}, \\ \text{BCSCTL1} &= \text{CALBC1_1MHZ}, \\ \text{DCOCTL} &= \text{CALDCO_1MHZ}, \\ \text{CPUOFF} &= 1, \text{SCG0} = 0, \text{SCG1} = 1, \\ \text{OSCOFF} &= 0 \end{split}$	25°C	2.2 V	22		μΑ
I _{LPM3,LFXT1}	Low-power mode 3 (LPM3) current ⁽⁴⁾	$ \begin{aligned} f_{DCO} &= f_{MCLK} = f_{SMCLK} = 0 \text{ MHz}, \\ f_{ACLK} &= 32768 \text{ Hz}, \\ CPUOFF &= 1, SCG0 = 1, SCG1 = 1, \\ OSCOFF &= 0 \end{aligned} $	25°C	2.2 V	0.7	1.5	μΑ
I _{LPM3,VLO}	Low-power mode 3 current, (LPM3) ⁽⁴⁾	$ \begin{aligned} &f_{DCO} = f_{MCLK} = f_{SMCLK} = 0 \text{ MHz}, \\ &f_{ACLK} \text{ from internal LF oscillator (VLO),} \\ &CPUOFF = 1, \ SCG0 = 1, \ SCG1 = 1, \\ &OSCOFF = 0 \end{aligned} $	25°C	2.2 V	0.5	0.7	μΑ
	1	$f_{DCO} = f_{MCLK} = f_{SMCLK} = 0 \text{ MHz},$	25°C		0.1	0.5	
I _{LPM4}	Low-power mode 4 (LPM4) current ⁽⁵⁾	f _{ACLK} = 0 Hz, CPUOFF = 1, SCG0 = 1, SCG1 = 1, OSCOFF = 1	85°C	2.2 V	0.8	1.7	μA

- (1) All inputs are tied to 0 V or to V_{CC}. Outputs do not source or sink any current.
- (2) The currents are characterized with a Micro Crystal CC4V-T1A SMD crystal with a load capacitance of 9 pF. The internal and external load capacitance is chosen to closely match the required 9 pF.
- (3) Current for brownout and WDT clocked by SMCLK included.
- (4) Current for brownout and WDT clocked by ACLK included.
- (5) Current for brownout included.

Typical Characteristics, Low-Power Mode Supply Currents





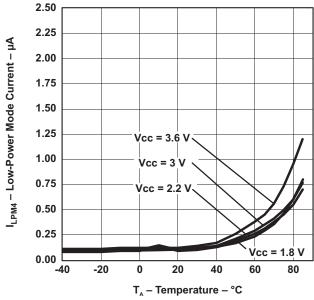


Figure 5. LPM4 Current vs Temperature



Schmitt-Trigger Inputs, Ports Px

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT
\/	Desitive gains input threshold valtage			0.45 V _{CC}		0.75 V _{CC}	V
V_{IT+}	Positive-going input threshold voltage		3 V	1.35		2.25	V
.,	No matical parisms in part through a laboration			0.25 V _{CC}		0.55 V _{CC}	\/
V_{IT-}	V _{IT} Negative-going input threshold voltage		3 V	0.75		1.65	V
V _{hys}	Input voltage hysteresis (V _{IT+} - V _{IT-})		3 V	0.3		1	V
R _{Pull}	Pullup/pulldown resistor	For pullup: V _{IN} = V _{SS} For pulldown: V _{IN} = V _{CC}	3 V	20	35	50	kΩ
Cı	Input capacitance	$V_{IN} = V_{SS}$ or V_{CC}			5		pF

Leakage Current, Ports Px

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	METER	TEST CONDITIONS	V _{CC}	MIN MAX	UNIT
I _{lkg(Px.y)} High-impedance lea	akage current	(1) (2)	3 V	±50	nA

- The leakage current is measured with V_{SS} or V_{CC} applied to the corresponding pin(s), unless otherwise noted. The leakage of the digital port pins is measured individually. The port pin is selected for input and the pullup/pulldown resistor is disabled.

Outputs, Ports Px

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
V_{OH}	High-level output voltage	$I_{(OHmax)} = -6 \text{ mA}^{(1)}$	3 V	\	/ _{CC} – 0.3		V
V_{OL}	Low-level output voltage	$I_{(OLmax)} = 6 \text{ mA}^{(1)}$	3 V	'	√ _{SS} + 0.3		V

⁽¹⁾ The maximum total current, I_(OHmax), and I_(OLmax), for all outputs combined should not exceed ±48 mA to hold the maximum voltage drop

Output Frequency, Ports Px

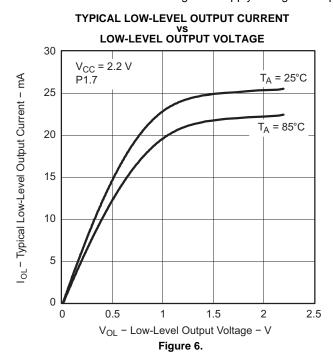
	PARAMETER	TEST CONDITIONS	V _{CC}	MIN TYP	MAX	UNIT
f _{Px.y}	Port output frequency (with load)	Px.y, $C_L = 20 \text{ pF}$, $R_L = 1 \text{ k}\Omega^{(1)}$ (2)	3 V	12		MHz
f _{Port_CLK}	Clock output frequency	$Px.y, C_L = 20 pF^{(2)}$	3 V	16		MHz

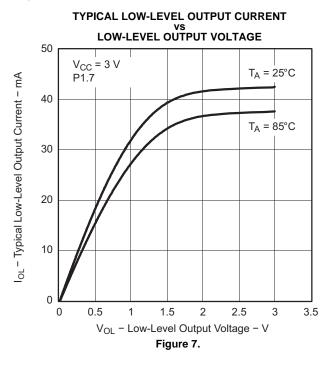
- A resistive divider with two 50-kΩ resistors between V_{CC} and V_{SS} is used as load. The output is connected to the center tap of the divider.
- The output voltage reaches at least 10% and 90% V_{CC} at the specified toggle frequency.



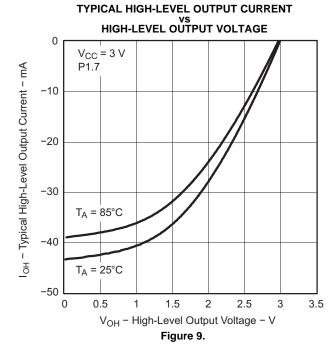
Typical Characteristics, Outputs

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)





TYPICAL HIGH-LEVEL OUTPUT CURRENT vs HIGH-LEVEL OUTPUT VOLTAGE 0 $V_{CC} = 2.2 \text{ V}$ I_{OH} - Typical High-Level Output Current - mA P1.7 -10-15 T_A = 85°C -20 $T_A = 25^{\circ}C$ -25 0 0.5 2 1.5 2.5 V_{OH} - High-Level Output Voltage - V Figure 8.





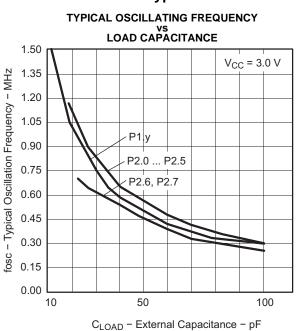
Pin-Oscillator Frequency - Ports Px

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	v_{cc}	MIN TYP	MAX	UNIT	
40	Don't autout assillation from	P1.y, $C_L = 10 \text{ pF}$, $R_L = 100 \text{ k}\Omega^{(1)(2)}$	3 V	1400		kHz	
fo _{P1.x}	Port output oscillation frequency	P1.y, $C_L = 20 \text{ pF}$, $R_L = 100 \text{ k}\Omega^{(1)(2)}$	3 V	900		KIZ	
	Dont cutout accillation frances	P2.0 to P2.5, $C_L = 10 \text{ pF}$, $R_L = 100 \text{ k}\Omega^{(1)(2)}$	2.1/	1800		kHz	
fo _{P2.x}	Port output oscillation frequency	P2.0 to P2.5, $C_L = 20 \text{ pF}$, $R_L = 100 \text{ k}\Omega^{(1)(2)}$	3 V	1000		kHz	
fo _{P2.6/7}	Port output oscillation frequency	P2.6 and P2.7, $C_L = 20 \text{ pF}$, $R_L = 100 \text{ k}\Omega^{(1)(2)}$	3 V	700		kHz	
	Dort output appillation fraguency	P3.y, $C_L = 10 \text{ pF}$, $R_L = 100 \text{ k}\Omega^{(1)(2)}$	3 V	1800		kHz	
fo _{P3.x}	Port output oscillation frequency	P3.y, $C_L = 20 \text{ pF}$, $R_L = 100 \text{ k}\Omega^{(1)(2)}$	3 V	1000		KΠZ	

A resistive divider with two 50-kΩ resistors between V_{CC} and V_{SS} is used as load. The output is connected to the center tap of the divider.

Typical Characteristics, Pin-Oscillator Frequency



A. One output active at a time.

Figure 10.



C_{LOAD} - External Capacitance - pF

A. One output active at a time.

Figure 11.

⁽²⁾ The output voltage reaches at least 10% and 90% V_{CC} at the specified toggle frequency.



POR, BOR (1)(2)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN TYP N	AX UNIT
V _{CC(start)}	See Figure 12	dV _{CC} /dt ≤ 3 V/s		0.7 × V _(B_IT)	V
$V_{(B_IT-)}$	See Figure 12 through Figure 14	dV _{CC} /dt ≤ 3 V/s		1.35	V
V _{hys(B_IT-)}	See Figure 12	dV _{CC} /dt ≤ 3 V/s		140	mV
t _{d(BOR)}	See Figure 12			2000	μs
t _(reset)	Pulse duration needed at RST/NMI pin to accepted reset internally		2.2 V	2	μs

- The current consumption of the brownout module is already included in the I_{CC} current consumption data. The voltage level V_(B_IT-) + V_{hys(B_IT-)}is ≤ 1.8 V.
- (2) During power up, the CPU begins code execution following a period of t_{d(BOR)} after V_{CC} = V_(B_IT-) + V_{hys(B_IT-)}. The default DCO settings must not be changed until V_{CC} ≥ V_{CC(min)}, where V_{CC(min)} is the minimum supply voltage for the desired operating frequency.



Figure 12. POR and BOR vs Supply Voltage



Typical Characteristics, POR and BOR

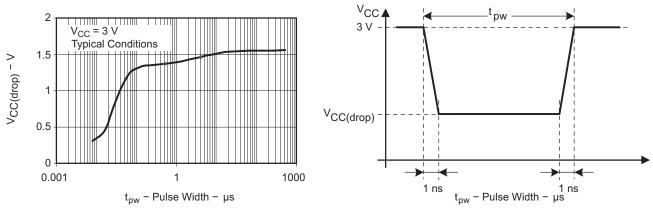


Figure 13. V_{CC(drop)} Level With a Square Voltage Drop to Generate a POR or BOR Signal

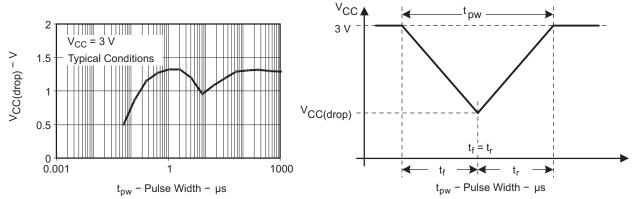


Figure 14. $V_{CC(drop)}$ Level With a Triangle Voltage Drop to Generate a POR or BOR Signal



Main DCO Characteristics

- All ranges selected by RSELx overlap with RSELx + 1: RSELx = 0 overlaps RSELx = 1, ... RSELx = 14 overlaps RSELx = 15.
- DCO control bits DCOx have a step size as defined by parameter S_{DCO}.
- Modulation control bits MODx select how often f_{DCO(RSEL,DCO+1)} is used within the period of 32 DCOCLK cycles. The frequency f_{DCO(RSEL,DCO)} is used for the remaining cycles. The frequency is an average equal to:

$$f_{average} = \frac{32 \times f_{DCO(RSEL,DCO)} \times f_{DCO(RSEL,DCO+1)}}{MOD \times f_{DCO(RSEL,DCO)} + (32 - MOD) \times f_{DCO(RSEL,DCO+1)}}$$

DCO Frequency

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
		RSELx < 14		1.8		3.6	V
V_{CC}	Supply voltage	RSELx = 14		2.2		3.6	V
		RSELx = 15		3		3.6	V
f _{DCO(0,0)}	DCO frequency (0, 0)	RSELx = 0, $DCOx = 0$, $MODx = 0$	3 V	0.06		0.14	MHz
$f_{DCO(0,3)}$	DCO frequency (0, 3)	RSELx = 0, $DCOx = 3$, $MODx = 0$	3 V	0.07		0.17	MHz
f _{DCO(1,3)}	DCO frequency (1, 3)	RSELx = 1, $DCOx = 3$, $MODx = 0$	3 V		0.15		MHz
$f_{DCO(2,3)}$	DCO frequency (2, 3)	RSELx = 2, $DCOx = 3$, $MODx = 0$	3 V		0.21		MHz
f _{DCO(3,3)}	DCO frequency (3, 3)	RSELx = 3, $DCOx = 3$, $MODx = 0$	3 V		0.30		MHz
f _{DCO(4,3)}	DCO frequency (4, 3)	RSELx = 4, $DCOx = 3$, $MODx = 0$	3 V		0.41		MHz
f _{DCO(5,3)}	DCO frequency (5, 3)	RSELx = 5, $DCOx = 3$, $MODx = 0$	3 V		0.58		MHz
f _{DCO(6,3)}	DCO frequency (6, 3)	RSELx = 6, $DCOx = 3$, $MODx = 0$	3 V	0.54		1.06	MHz
f _{DCO(7,3)}	DCO frequency (7, 3)	RSELx = 7, $DCOx = 3$, $MODx = 0$	3 V	0.80		1.50	MHz
f _{DCO(8,3)}	DCO frequency (8, 3)	RSELx = 8, $DCOx = 3$, $MODx = 0$	3 V		1.6		MHz
$f_{DCO(9,3)}$	DCO frequency (9, 3)	RSELx = 9, $DCOx = 3$, $MODx = 0$	3 V		2.3		MHz
f _{DCO(10,3)}	DCO frequency (10, 3)	RSELx = 10, $DCOx = 3$, $MODx = 0$	3 V		3.4		MHz
f _{DCO(11,3)}	DCO frequency (11, 3)	RSELx = 11, $DCOx = 3$, $MODx = 0$	3 V		4.25		MHz
f _{DCO(12,3)}	DCO frequency (12, 3)	RSELx = 12, $DCOx = 3$, $MODx = 0$	3 V	4.30		7.30	MHz
f _{DCO(13,3)}	DCO frequency (13, 3)	RSELx = 13, $DCOx = 3$, $MODx = 0$	3 V	6.00		9.60	MHz
f _{DCO(14,3)}	DCO frequency (14, 3)	RSELx = 14, $DCOx = 3$, $MODx = 0$	3 V	8.60		13.9	MHz
f _{DCO(15,3)}	DCO frequency (15, 3)	RSELx = 15, $DCOx = 3$, $MODx = 0$	3 V	12.0		18.5	MHz
f _{DCO(15,7)}	DCO frequency (15, 7)	RSELx = 15, $DCOx = 7$, $MODx = 0$	3 V	16.0		26.0	MHz
S _{RSEL}	Frequency step between range RSEL and RSEL+1	$S_{RSEL} = f_{DCO(RSEL+1,DCO)}/f_{DCO(RSEL,DCO)}$	3 V		1.35		ratio
S _{DCO}	Frequency step between tap DCO and DCO+1	$S_{DCO} = f_{DCO(RSEL,DCO+1)}/f_{DCO(RSEL,DCO)}$	3 V		1.08		ratio
Duty cycle		Measured at SMCLK output	3 V		50		%



Calibrated DCO Frequencies, Tolerance

PARAMETER	TEST CONDITIONS	T _A	V _{cc}	MIN	TYP	MAX	UNIT
1-MHz tolerance over temperature ⁽¹⁾	BCSCTL1 = CALBC1_1MHZ, DCOCTL = CALDCO_1MHZ, calibrated at 30°C and 3 V	0°C to 85°C	3 V	-3	±0.5	+3	%
1-MHz tolerance over V _{CC}	BCSCTL1 = CALBC1_1MHZ, DCOCTL = CALDCO_1MHZ, calibrated at 30°C and 3 V	30°C	1.8 V to 3.6 V	-3	±2	+3	%
1-MHz tolerance overall	BCSCTL1 = CALBC1_1MHZ, DCOCTL = CALDCO_1MHZ, calibrated at 30°C and 3 V	-40°C to 85°C	1.8 V to 3.6 V	-6	±3	+6	%
8-MHz tolerance over temperature ⁽¹⁾	BCSCTL1 = CALBC1_8MHZ, DCOCTL = CALDCO_8MHZ, calibrated at 30°C and 3 V	0°C to 85°C	3 V	-3	±0.5	+3	%
8-MHz tolerance over V _{CC}	BCSCTL1 = CALBC1_8MHZ, DCOCTL = CALDCO_8MHZ, calibrated at 30°C and 3 V	30°C	2.2 V to 3.6 V	-3	±2	+3	%
8-MHz tolerance overall	BCSCTL1 = CALBC1_8MHZ, DCOCTL = CALDCO_8MHZ, calibrated at 30°C and 3 V	-40°C to 85°C	2.2 V to 3.6 V	-6	±3	+6	%
12-MHz tolerance over temperature ⁽¹⁾	BCSCTL1 = CALBC1_12MHZ, DCOCTL = CALDCO_12MHZ, calibrated at 30°C and 3 V	0°C to 85°C	3 V	-3	±0.5	+3	%
12-MHz tolerance over V _{CC}	BCSCTL1 = CALBC1_12MHZ, DCOCTL = CALDCO_12MHZ, calibrated at 30°C and 3 V	30°C	2.7 V to 3.6 V	-3	±2	+3	%
12-MHz tolerance overall	BCSCTL1 = CALBC1_12MHZ, DCOCTL = CALDCO_12MHZ, calibrated at 30°C and 3 V	-40°C to 85°C	2.7 V to 3.6 V	-6	±3	+6	%
16-MHz tolerance over temperature ⁽¹⁾	BCSCTL1 = CALBC1_16MHZ, DCOCTL = CALDCO_16MHZ, calibrated at 30°C and 3 V	0°C to 85°C	3 V	-3	±0.5	+3	%
16-MHz tolerance over V _{CC}	BCSCTL1 = CALBC1_16MHZ, DCOCTL = CALDCO_16MHZ, calibrated at 30°C and 3 V	30°C	3.3 V to 3.6 V	-3	±2	+3	%
16-MHz tolerance overall	BCSCTL1 = CALBC1_16MHZ, DCOCTL = CALDCO_16MHZ, calibrated at 30°C and 3 V	-40°C to 85°C	3.3 V to 3.6 V	-6	±3	+6	%

⁽¹⁾ This is the frequency change from the measured frequency at 30°C over temperature.



Wake-Up From Lower-Power Modes (LPM3, LPM4)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	0 117	. 5	`		,		
	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT
t _{DCO,LPM3/4}	DCO clock wake-up time from LPM3 or LPM4 (1)	BCSCTL1 = CALBC1_1MHz, DCOCTL = CALDCO_1MHz	3 V		1.5		μs
t _{CPU,LPM3/4}	CPU wake-up time from LPM3 or LPM4 (2)			t	1/f _{MCLK} + Clock,LPM3/4		

⁽¹⁾ The DCO clock wake-up time is measured from the edge of an external wake-up signal (e.g., port interrupt) to the first clock edge observable externally on a clock pin (MCLK or SMCLK).

Typical Characteristics, DCO Clock Wake-Up Time From LPM3 or LPM4



Figure 15. DCO Wake-Up Time From LPM3 vs DCO Frequency

⁽²⁾ Parameter applicable only if DCOCLK is used for MCLK.



Crystal Oscillator, XT1, Low-Frequency Mode⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT
f _{LFXT1,LF}	LFXT1 oscillator crystal frequency, LF mode 0, 1	XTS = 0, LFXT1Sx = 0 or 1	1.8 V to 3.6 V		32768		Hz
f _{LFXT1,LF,logic}	LFXT1 oscillator logic level square wave input frequency, LF mode	XTS = 0, XCAPx = 0, LFXT1Sx = 3	1.8 V to 3.6 V	10000	32768	50000	Hz
04	Oscillation allowance for	$XTS = 0$, $LFXT1Sx = 0$, $f_{LFXT1,LF} = 32768$ Hz, $C_{L,eff} = 6$ pF			500		1.0
OA _{LF}	LF crystals	$XTS = 0$, $LFXT1Sx = 0$, $f_{LFXT1,LF} = 32768$ Hz, $C_{L,eff} = 12$ pF			200		kΩ
	Integrated effective load	XTS = 0, $XCAPx = 0$			1		
		XTS = 0, XCAPx = 1			5.5		F
$C_{L,eff}$	capacitance, LF mode (2)	XTS = 0, XCAPx = 2			8.5		pF
		XTS = 0, XCAPx = 3			11		
Duty cycle	LF mode	XTS = 0, Measured at P2.0/ACLK, f _{LFXT1,LF} = 32768 Hz	2.2 V	30	50	70	%
f _{Fault,LF}	Oscillator fault frequency, LF mode ⁽³⁾	XTS = 0, XCAPx = 0, LFXT1Sx = 3 ⁽⁴⁾	2.2 V	10		10000	Hz

- (1) To improve EMI on the XT1 oscillator, the following guidelines should be observed.
 - (a) Keep the trace between the device and the crystal as short as possible.
 - (b) Design a good ground plane around the oscillator pins.
 - (c) Prevent crosstalk from other clock or data lines into oscillator pins XIN and XOUT.
 - (d) Avoid running PCB traces underneath or adjacent to the XIN and XOUT pins.
 - (e) Use assembly materials and praxis to avoid any parasitic load on the oscillator XIN and XOUT pins.
 - (f) If conformal coating is used, ensure that it does not induce capacitive/resistive leakage between the oscillator pins.
 - (g) Do not route the XOUT line to the JTAG header to support the serial programming adapter as shown in other documentation. This signal is no longer required for the serial programming adapter.
- (2) Includes parasitic bond and package capacitance (approximately 2 pF per pin).
 - Since the PCB adds additional capacitance, it is recommended to verify the correct load by measuring the ACLK frequency. For a correct setup, the effective load capacitance should always match the specification of the used crystal.
- (3) Frequencies below the MIN specification set the fault flag. Frequencies above the MAX specification do not set the fault flag. Frequencies in between might set the flag.
- (4) Measured with logic-level input frequency but also applies to operation with crystals.

Internal Very-Low-Power Low-Frequency Oscillator (VLO)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	T _A	V _{cc}	MIN	TYP	MAX	UNIT
f_{VLO}	VLO frequency	-40°C to 85°C	3 V	4	12	20	kHz
df_{VLO}/d_{T}	VLO frequency temperature drift	-40°C to 85°C	3 V		0.5		%/°C
df_{VLO}/dV_{CC}	VLO frequency supply voltage drift	25°C	1.8 V to 3.6 V	·	4		%/V

Timer A

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
f_{TA}	Timer_A input clock frequency	SMCLK, duty cycle = 50% ± 10%		f _{SYSTEM}			MHz
t _{TA,cap}	Timer_A capture timing	TA0, TA1	3 V	20			ns



USCI (UART Mode)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		ETER TEST CONDITIONS V _{CC}		MIN	TYP	MAX	UNIT
f _{USCI}	USCI input clock frequency	SMCLK, duty cycle = 50% ± 10%			f _{SYSTEM}		MHz
f _{max,BITCLK}	Maximum BITCLK clock frequency (equals baudrate in MBaud) (1)		3 V	2			MHz
t _T	UART receive deglitch time (2)		3 V	50	100	600	ns

⁽¹⁾ The DCO wake-up time must be considered in LPM3 and LPM4 for baud rates above 1 MHz.

USCI (SPI Master Mode)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 16 and Figure 17)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
f _{USCI}	USCI input clock frequency	SMCLK, duty cycle = 50% ± 10%				f_{SYSTEM}	MHz
t _{SU,MI}	SOMI input data setup time		3 V	75			ns
t _{HD,MI}	SOMI input data hold time		3 V	0			ns
t _{VALID,MO}	SIMO output data valid time	UCLK edge to SIMO valid, C _L = 20 pF	3 V			20	ns

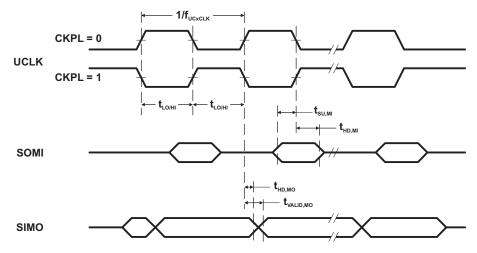


Figure 16. SPI Master Mode, CKPH = 0

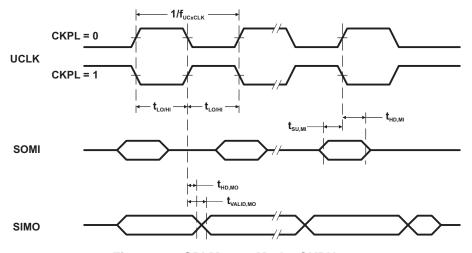


Figure 17. SPI Master Mode, CKPH = 1

⁽²⁾ Pulses on the UART receive input (UCxRX) shorter than the UART receive deglitch time are suppressed. To ensure that pulses are correctly recognized, their width should exceed the maximum specification of the deglitch time.



USCI (SPI Slave Mode)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 18 and Figure 19)

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
t _{STE,LEAD}	STE lead time, STE low to clock		3 V		50		ns
t _{STE,LAG}	STE lag time, Last clock to STE high		3 V	10			ns
t _{STE,ACC}	STE access time, STE low to SOMI data out		3 V		50		ns
t _{STE,DIS}	STE disable time, STE high to SOMI high impedance		3 V		50		ns
t _{SU,SI}	SIMO input data setup time		3 V	15			ns
t _{HD,SI}	SIMO input data hold time		3 V	10			ns
t _{VALID,SO}	SOMI output data valid time	UCLK edge to SOMI valid, C _L = 20 pF	3 V		50	75	ns

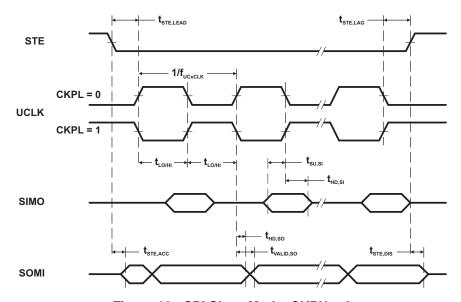


Figure 18. SPI Slave Mode, CKPH = 0

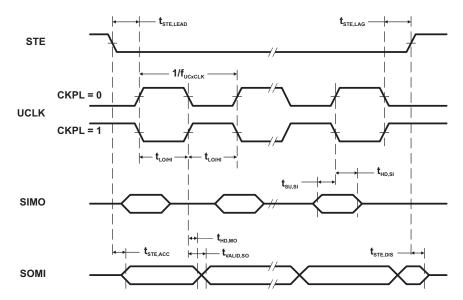


Figure 19. SPI Slave Mode, CKPH = 1



USCI (I2C Mode)

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
f _{USCI}	USCI input clock frequency	SMCLK, duty cycle = 50% ± 10%				f _{SYSTEM}	MHz
f _{SCL}	SCL clock frequency		3 V	0		400	kHz
	Hold time (repeated) START	f _{SCL} ≤ 100 kHz	2.1/	4.0			
t _{HD,STA}	Hold time (repeated) START	f _{SCL} > 100 kHz	3 V	0.6			μs
	Setup time for a repeated START	f _{SCL} ≤ 100 kHz	3 V	4.7			110
t _{SU,STA}		f _{SCL} > 100 kHz	3 V	0.6			μs
$t_{HD,DAT}$	Data hold time		3 V	0			ns
t _{SU,DAT}	Data setup time		3 V	250			ns
t _{SU,STO}	Setup time for STOP		3 V	4.0			μs
t_{SP}	Pulse width of spikes suppressed by input filter		3 V	50	100	600	ns

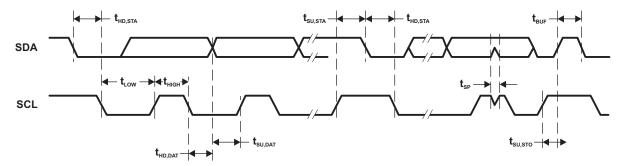


Figure 20. I2C Mode Timing



10-Bit ADC, Power Supply and Input Range Conditions (MSP430G2x33 Only)

	PARAMETER	TEST CONDITIONS	T _A	V _{cc}	MIN	TYP	MAX	UNIT	
V _{CC}	Analog supply voltage	V _{SS} = 0 V			2.2		3.6	V	
V _{Ax}	Analog input voltage (2)	All Ax terminals, Analog inputs selected in ADC10AE register		3 V	0		V_{CC}	V	
I _{ADC10}	ADC10 supply current ⁽³⁾	f _{ADC10CLK} = 5.0 MHz, ADC10ON = 1, REFON = 0, ADC10SHT0 = 1, ADC10SHT1 = 0, ADC10DIV = 0	25°C	3 V		0.6		mA	
	Reference supply current,	f _{ADC10CLK} = 5.0 MHz, ADC10ON = 0, REF2_5V = 0, REFON = 1, REFOUT = 0	- 25°C	3 V		0.25		A	
I _{REF+}	Reference supply current, reference buffer disabled ⁽⁴⁾	f _{ADC10CLK} = 5.0 MHz, ADC10ON = 0, REF2_5V = 1, REFON = 1, REFOUT = 0		25 C	25 C			0.25	
I _{REFB,0}	Reference buffer supply current with ADC10SR = $0^{(4)}$	f _{ADC10CLK} = 5.0 MHz, ADC10ON = 0, REFON = 1, REF2_5V = 0, REFOUT = 1, ADC10SR = 0	25°C	3 V		1.1		mA	
I _{REFB,1}	Reference buffer supply current with ADC10SR = 1 (4)	f _{ADC10CLK} = 5.0 MHz, ADC10ON = 0, REFON = 1, REF2_5V = 0, REFOUT = 1, ADC10SR = 1	25°C	3 V		0.5		mA	
Cı	Input capacitance	Only one terminal Ax can be selected at one time	25°C	3 V			27	pF	
R_{l}	Input MUX ON resistance	$0 \text{ V} \leq \text{V}_{Ax} \leq \text{V}_{CC}$	25°C	3 V		1000		Ω	

The leakage current is defined in the leakage current table with Px.y/Ax parameter.

The analog input voltage range must be within the selected reference voltage range V_{R+} to V_{R-} for valid conversion results.

The internal reference supply current is not included in current consumption parameter I_{ADC10} . The internal reference current is supplied via terminal V_{CC} . Consumption is independent of the ADC10ON control bit, unless a conversion is active. The REFON bit enables the built-in reference to settle before starting an A/D conversion.



10-Bit ADC, Built-In Voltage Reference (MSP430G2x33 Only)

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
V	Positive built-in reference	I _{VREF+} ≤ 1 mA, REF2_5V = 0		2.2			V
$V_{CC,REF+}$	analog supply voltage range	I _{VREF+} ≤ 1 mA, REF2_5V = 1		2.9			V
M	Positive built-in reference	$I_{VREF+} \le I_{VREF+} max$, REF2_5V = 0	3 V	1.41	1.5	1.59	V
V _{REF+}	voltage	$I_{VREF+} \le I_{VREF+}$ max, REF2_5V = 1	3 V	2.35	2.5	2.65	V
I _{LD,VREF+}	Maximum VREF+ load current		3 V			±1	mA
	VDEE , load regulation	I_{VREF+} = 500 μA ± 100 μA, Analog input voltage V_{Ax} ≉ 0.75 V, REF2_5V = 0	3 V			±2	LSB
	VREF+ load regulation	I_{VREF+} = 500 μA ± 100 μA, Analog input voltage V_{Ax} ≉ 1.25 V, REF2_5V = 1	3 V			±2	LOB
	V _{REF+} load regulation response time	$I_{VREF+} = 100 \mu A \rightarrow 900 \mu A,$ $V_{Ax} \neq 0.5 \times VREF+,$ Error of conversion result ≤ 1 LSB, ADC10SR = 0	3 V			400	ns
C _{VREF+}	Maximum capacitance at pin VREF+	I _{VREF+} ≤ ±1 mA, REFON = 1, REFOUT = 1	3 V			100	pF
TC _{REF+}	Temperature coefficient	I _{VREF+} = const with 0 mA ≤ I _{VREF+} ≤ 1 mA	3 V			±100	ppm/ °C
t _{REFON}	Settling time of internal reference voltage to 99.9% VREF	$I_{VREF+} = 0.5 \text{ mA}, REF2_5V = 0,$ REFON = 0 \rightarrow 1	3.6 V			30	μs
t _{REFBURST}	Settling time of reference buffer to 99.9% VREF	I _{VREF+} = 0.5 mA, REF2_5V = 1, REFON = 1, REFBURST = 1, ADC10SR = 0	3 V			2	μs



10-Bit ADC, External Reference⁽¹⁾ (MSP430G2x33 Only)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP I	MAX	UNIT	
VEREF+	Positive external reference input	VEREF+ > VEREF-, SREF1 = 1, SREF0 = 0			1.4		V_{CC}	V
	voltage range (2)	VEREF- \leq VEREF+ \leq V _{CC} $-$ 0.15 V, SREF1 = 1, SREF0 = 1 (3)		1.4		3	V	
VEREF-	Negative external reference input voltage range ⁽⁴⁾	VEREF+ > VEREF-		0		1.2	٧	
ΔVEREF	Differential external reference input voltage range, ΔVEREF = VEREF+ – VEREF-	VEREF+ > VEREF- (5)		1.4		V_{CC}	V	
	Static input current into VEDEE	$0 \text{ V} \leq \text{VEREF+} \leq \text{V}_{CC}$, SREF1 = 1, SREF0 = 0	3 V	±1				
IVEREF+	Static input current into VEREF+	$0 \text{ V} \le \text{VEREF+} \le \text{V}_{\text{CC}} - 0.15 \text{ V} \le 3 \text{ V},$ SREF1 = 1, SREF0 = $1^{(3)}$	3 V	·	0		μA	
I _{VEREF}	Static input current into VEREF-	0 V ≤ VEREF- ≤ V _{CC}	3 V		±1		μΑ	

- (1) The external reference is used during conversion to charge and discharge the capacitance array. The input capacitance, C_I, is also the dynamic load for an external reference during conversion. The dynamic impedance of the reference supply should follow the recommendations on analog-source impedance to allow the charge to settle for 10-bit accuracy.
- (2) The accuracy limits the minimum positive external reference voltage. Lower reference voltage levels may be applied with reduced accuracy requirements.
- (3) Under this condition the external reference is internally buffered. The reference buffer is active and requires the reference buffer supply current I_{REFB}. The current consumption can be limited to the sample and conversion period with REBURST = 1.
- (4) The accuracy limits the maximum negative external reference voltage. Higher reference voltage levels may be applied with reduced accuracy requirements.
- (5) The accuracy limits the minimum external differential reference voltage. Lower differential reference voltage levels may be applied with reduced accuracy requirements.

10-Bit ADC, Timing Parameters (MSP430G2x33 Only)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITION	ONS	V _{CC}	MIN	TYP	MAX	UNIT
£	ADC10 input clock	For specified performance of	ADC10SR = 0	3 V	0.45		6.3	MHz
TADC10CLK	frequency	ADC10 linearity parameters	ADC10SR = 1	3 V	0.45		1.5	IVI□Z
f _{ADC10OSC}	ADC10 built-in oscillator frequency	ADC10DIVx = 0, ADC10SSELx = 0, f _{ADC10CLK} = f _{ADC10OSC}		3 V	3.7		6.3	MHz
	Conversion time	ADC10 built-in oscillator, ADC1 $f_{ADC10CLK} = f_{ADC10OSC}$	10SSELx = 0,	3 V	2.06		3.51	
t _{CONVERT}		f _{ADC10CLK} from ACLK, MCLK, o ADC10SSELx ≠ 0	or SMCLK:			13 × C10DIV ×		μs
t _{ADC10ON}	Turn-on settling time of the ADC	(1)					100	ns

The condition is that the error in a conversion started after t_{ADC100N} is less than ±0.5 LSB. The reference and input signal are already settled.

10-Bit ADC, Linearity Parameters (MSP430G2x33 Only)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT
E _I	Integral linearity error		3 V			±1	LSB
E _D	Differential linearity error		3 V			±1	LSB
Eo	Offset error	Source impedance R_S < 100 Ω	3 V			±1	LSB
E _G	Gain error		3 V		±1.1	±2	LSB
E _T	Total unadjusted error		3 V		±2	±5	LSB



10-Bit ADC, Temperature Sensor and Built-In V_{MID} (MSP430G2x33 Only)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT
I _{SENSOR}	Temperature sensor supply current ⁽¹⁾	REFON = 0, INCHx = 0Ah, $T_A = 25$ °C	3 V		60		μA
TC _{SENSOR}		ADC10ON = 1, INCHx = 0Ah (2)	3 V		3.55		mV/°C
t _{Sensor(sample)}	Sample time required if channel 10 is selected (3)	ADC10ON = 1, INCHx = 0Ah, Error of conversion result ≤ 1 LSB	3 V	30			μs
I _{VMID}	Current into divider at channel 11	ADC10ON = 1, INCHx = 0Bh	3 V			(4)	μA
V _{MID}	V _{CC} divider at channel 11	ADC10ON = 1, INCHx = 0Bh, $V_{MID} \neq 0.5 \times V_{CC}$	3 V		1.5		V
t _{VMID(sample)}	Sample time required if channel 11 is selected ⁽⁵⁾	ADC10ON = 1, INCHx = 0Bh, Error of conversion result ≤ 1 LSB	3 V	1220			ns

⁽¹⁾ The sensor current I_{SENSOR} is consumed if (ADC10ON = 1 and REFON = 1) or (ADC10ON = 1 and INCH = 0Ah and sample signal is high). When REFON = 1, I_{SENSOR} is included in I_{REF+}. When REFON = 0, I_{SENSOR} applies during conversion of the temperature sensor input (INCH = 0Ah).

Flash Memory

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
V _{CC(PGM/ERASE)}	Program and erase supply voltage			2.2		3.6	V
f_{FTG}	Flash timing generator frequency			257		476	kHz
I _{PGM}	Supply current from V _{CC} during program		2.2 V/3.6 V		1	5	mA
I _{ERASE}	Supply current from V _{CC} during erase		2.2 V/3.6 V		1	7	mA
t _{CPT}	Cumulative program time ⁽¹⁾		2.2 V/3.6 V			10	ms
t _{CMErase}	Cumulative mass erase time		2.2 V/3.6 V	20			ms
	Program and erase endurance			10 ⁴	10 ⁵		cycles
t _{Retention}	Data retention duration	$T_J = 25^{\circ}C$		100			years
t _{Word}	Word or byte program time	(2)			30		t _{FTG}
t _{Block, 0}	Block program time for first byte or word	(2)			25		t _{FTG}
t _{Block, 1-63}	Block program time for each additional byte or word	(2)			18		t _{FTG}
t _{Block, End}	Block program end-sequence wait time	(2)			6		t _{FTG}
t _{Mass Erase}	Mass erase time	(2)			10593		t _{FTG}
t _{Seg Erase}	Segment erase time	(2)			4819		t _{FTG}

⁽¹⁾ The cumulative program time must not be exceeded when writing to a 64-byte flash block. This parameter applies to all programming methods: individual word/byte write and block write modes.

⁽²⁾ The following formula can be used to calculate the temperature sensor output voltage:

 $V_{Sensor,typ} = TC_{Sensor} (273 + T [^{\circ}C]) + V_{Offset,sensor} [mV] \text{ or}$

 $V_{Sensor,typ} = TC_{Sensor} T [^{\circ}C] + V_{Sensor}(T_A = 0^{\circ}C) [mV]$ 3) The typical equivalent impedance of the sensor is 51 k Ω . The sample time required includes the sensor-on time $t_{SENSOR(on)}$.

⁽⁴⁾ No additional current is needed. The $V_{\mbox{\scriptsize MID}}$ is used during sampling.

⁽⁵⁾ The on-time t_{VMID(on)} is included in the sampling time t_{VMID(sample)}; no additional on time is needed.

⁽²⁾ These values are hardwired into the Flash Controller's state machine ($t_{FTG} = 1/f_{FTG}$).



RAM

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
V _(RAMh)	RAM retention supply voltage (1)	CPU halted	1.6		V

⁽¹⁾ This parameter defines the minimum supply voltage V_{CC} when the data in RAM remains unchanged. No program execution should happen during this supply voltage condition.

JTAG and Spy-Bi-Wire Interface

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

			•		•		
	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT
f _{SBW}	Spy-Bi-Wire input frequency		2.2 V	0		20	MHz
t _{SBW,Low}	Spy-Bi-Wire low clock pulse length		2.2 V	0.025		15	μs
t _{SBW,En}	Spy-Bi-Wire enable time (TEST high to acceptance of first clock edge (1))		2.2 V			1	μs
t _{SBW,Ret}	Spy-Bi-Wire return to normal operation time		2.2 V	15		100	μs
f _{TCK}	TCK input frequency ⁽²⁾		2.2 V	0		5	MHz
R _{Internal}	Internal pulldown resistance on TEST		2.2 V	25	60	90	kΩ

⁽¹⁾ Tools accessing the Spy-Bi-Wire interface need to wait for the maximum t_{SBW,En} time after pulling the TEST/SBWCLK pin high before applying the first SBWCLK clock edge.

JTAG Fuse⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

		• •			
	PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
$V_{CC(FB)}$	Supply voltage during fuse-blow condition	T _A = 25°C	2.5		V
V_{FB}	Voltage level on TEST for fuse blow		6	7	V
I _{FB}	Supply current into TEST during fuse blow			100	mA
t _{FB}	Time to blow fuse			1	ms

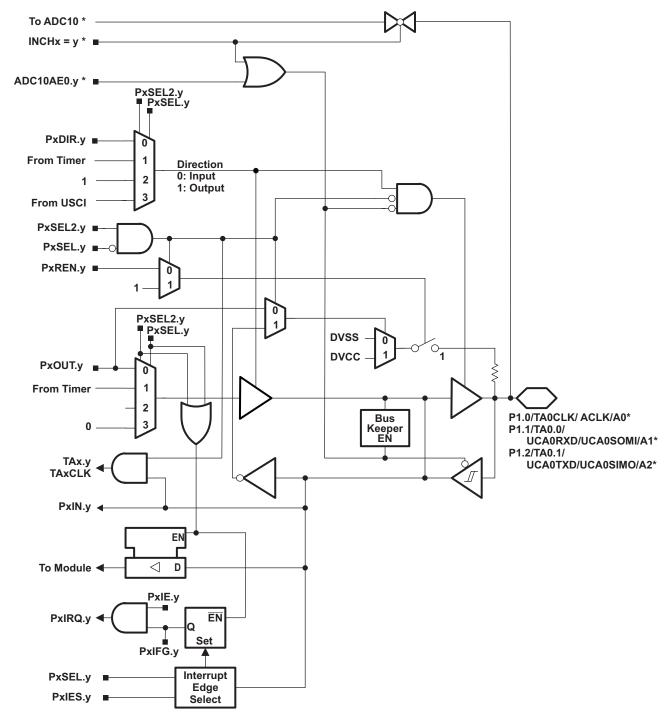
⁽¹⁾ Once the fuse is blown, no further access to the JTAG/Test, Spy-Bi-Wire, and emulation feature is possible, and JTAG is switched to bypass mode.

⁽²⁾ f_{TCK} may be restricted to meet the timing requirements of the module selected.



PORT SCHEMATICS

Port P1 Pin Schematic: P1.0 to P1.2, Input/Output With Schmitt Trigger



^{*} Note: MSP430G2x33 devices only. MSP430G2x03 devices have no ADC10.

Copyright © 2011–2013, Texas Instruments Incorporated



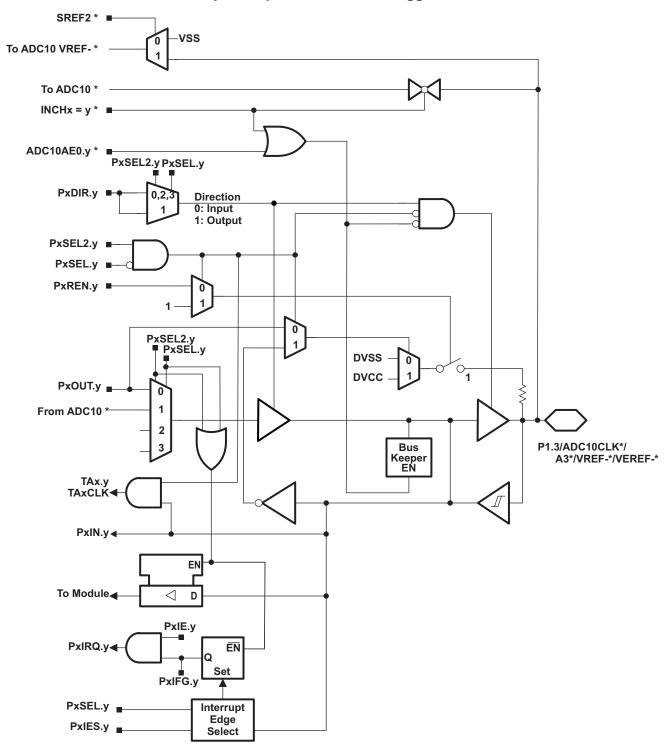
Table 16. Port P1 (P1.0 to P1.2) Pin Functions

DIN MARKE				CONTROL BIT	S / SIGNALS ⁽¹⁾	
PIN NAME (P1.x)	x	FUNCTION	P1DIR.x	P1SEL.x	P1SEL2.x	ADC10AE.x (INCH.y = 1) ⁽²⁾
P1.0/		P1.x (I/O)	I: 0; O: 1	0	0	0
TA0CLK/		TA0.TACLK	0	1	0	0
ACLK/	0	ACLK	1	1	0	0
A0 ⁽²⁾ /		A0	X	Х	Х	1 (y = 0)
Pin Osc		Capacitive sensing	X	0	1	0
P1.1/		P1.x (I/O)	I: 0; O: 1	0	0	0
TA0.0/		TA0.0	1	1	0	0
		TA0.CCI0A	0	1	0	0
UCA0RXD/	1	UCA0RXD	from USCI	1	1	0
UCA0SOMI/		UCA0SOMI	from USCI	1	1	0
A1 ⁽²⁾ /		A1	X	Х	Х	1 (y = 1)
Pin Osc		Capacitive sensing	X	0	1	0
P1.2/		P1.x (I/O)	I: 0; O: 1	0	0	0
TA0.1/		TA0.1	1	1	0	0
		TA0.CCI1A	0	1	0	0
UCA0TXD/	2	UCA0TXD	from USCI	1	1	0
UCA0SIMO/		UCA0SIMO	from USCI	1	1	0
A2 ⁽²⁾ /		A2	Х	Х	Х	1 (y = 2)
Pin Osc		Capacitive sensing	Х	0	1	0

⁽¹⁾ X = don't care(2) MSP430G2x33 devices only



Port P1 Pin Schematic: P1.3, Input/Output With Schmitt Trigger



^{*} Note: MSP430G2x33 devices only. MSP430G2x03 devices have no ADC10.

Copyright © 2011–2013, Texas Instruments Incorporated



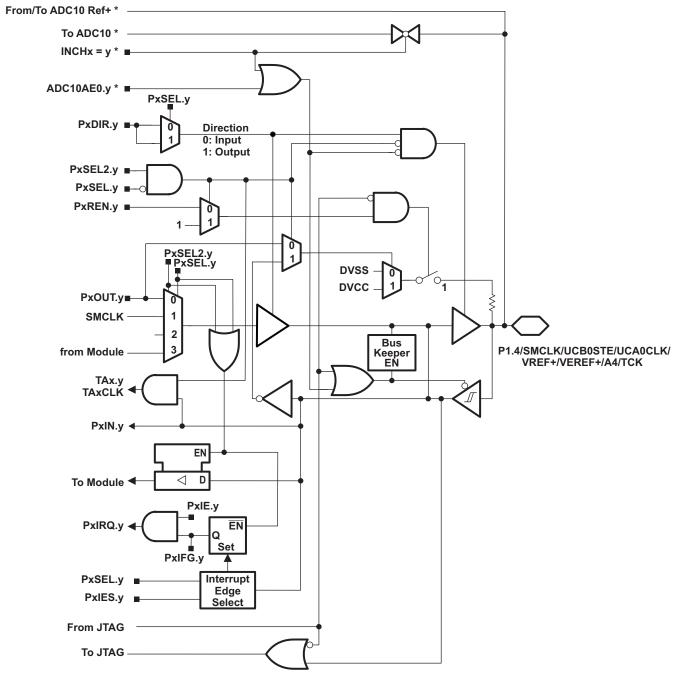
Table 17. Port P1 (P1.3) Pin Functions

PIN NAME	x	FUNCTION	CONTROL BITS / SIGNALS ⁽¹⁾					
(P1.x)			P1DIR.x	P1SEL.x	P1SEL2.x	ADC10AE.x $(INCH.x = 1)^{(2)}$		
P1.3/		P1.x (I/O)	I: 0; O: 1	0	0	0		
ADC10CLK ⁽²⁾ /		ADC10CLK	1	1	0	0		
A3 ⁽²⁾ /	3	A3	X	X	X	1 (y = 3)		
VREF- ⁽²⁾ /	3	VREF-	X	X	X	1		
VEREF-(2)/		VEREF-	X	X	X	1		
Pin Osc		Capacitive sensing	X	0	1	0		

⁽¹⁾ X = don't care(2) MSP430G2x33 devices only



Port P1 Pin Schematic: P1.4, Input/Output With Schmitt Trigger



^{*} Note: MSP430G2x33 devices only. MSP430G2x03 devices have no ADC10.



Table 18. Port P1 (P1.4) Pin Functions

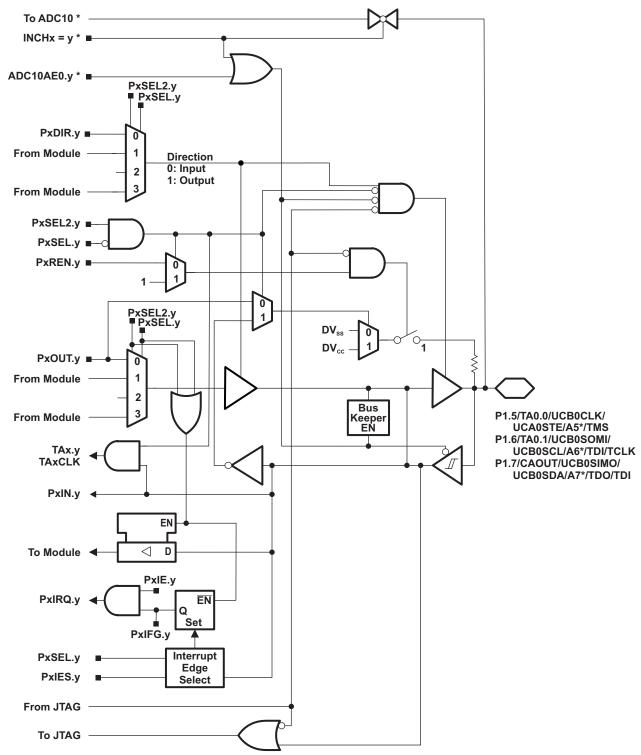
				CONTR	ROL BITS / SIGN	IALS ⁽¹⁾	
PIN NAME (P1.x)	x	FUNCTION	P1DIR.x	P1SEL.x	P1SEL2.x	ADC10AE.x (INCH.x = 1) ⁽²⁾	JTAG Mode
P1.4/		P1.x (I/O)	I: 0; O: 1	0	0	0	0
SMCLK/		SMCLK	1	1	0	0	0
UCB0STE/		UCB0STE	from USCI	1	1	0	0
UCA0CLK/		UCA0CLK	from USCI	1	1	0	0
VREF+(2)/	4	VREF+	Х	Х	Х	1	0
VEREF+(2)/		VEREF+	X	X	X	1	0
A4 ⁽²⁾ /		A4	X	X	X	1 (y = 4)	0
TCK/		TCK	Х	Х	Х	0	1
Pin Osc		Capacitive sensing	Х	0	1	0	0

⁽¹⁾ X = don't care

⁽²⁾ MSP430G2x33 devices only



Port P1 Pin Schematic: P1.5 to P1.7, Input/Output With Schmitt Trigger



^{*} Note: MSP430G2x33 devices only. MSP430G2x03 devices have no ADC10.



Table 19. Port P1 (P1.5 to P1.7) Pin Functions

		FUNCTION		CONTI	ROL BITS / SIG	NALS ⁽¹⁾	
PIN NAME (P1.x)	x		P1DIR.x	P1SEL.x	P1SEL2.x	ADC10AE.x (INCH.x = 1) ⁽²⁾	JTAG Mode
P1.5/		P1.x (I/O)	I: 0; O: 1	0	0	0	0
TA0.0/		TA0.0	1	1	0	0	0
UCB0CLK/		UCB0CLK	from USCI	1	1	0	0
UCA0STE/	5	UCA0STE	from USCI	1	1	0	0
A5 ⁽²⁾ /		A5	Х	X	Х	1 (y = 5)	0
TMS		TMS	Х	Х	Х	0	1
Pin Osc		Capacitive sensing	Х	0	1	0	0
P1.6/		P1.x (I/O)	I: 0; O: 1	0	0	0	0
TA0.1/		TA0.1	1	1	0	0	0
UCB0SOMI/		UCB0SOMI	from USCI	1	1	0	0
UCB0SCL/	6	UCB0SCL	from USCI	1	1	0	0
A6 ⁽²⁾ /		A6	X	Х	Х	1 (y = 6)	0
TDI/TCLK/		TDI/TCLK	Х	Х	Х	0	1
Pin Osc		Capacitive sensing	Х	0	1	0	0
P1.7/		P1.x (I/O)	I: 0; O: 1	0	0	0	0
UCB0SIMO/		UCB0SIMO	from USCI	1	1	0	0
UCB0SDA/	7	UCB0SDA	from USCI	1	1	0	0
A7 ⁽²⁾ /	′	A7	Х	Х	Х	1 (y = 7)	0
TDO/TDI/		TDO/TDI	X	Х	Х	0	1
Pin Osc		Capacitive sensing	Х	0	1	0	0

⁽¹⁾ X = don't care

⁽²⁾ MSP430G2x33 devices only



Port P2 Pin Schematic: P2.0 to P2.5, Input/Output With Schmitt Trigger

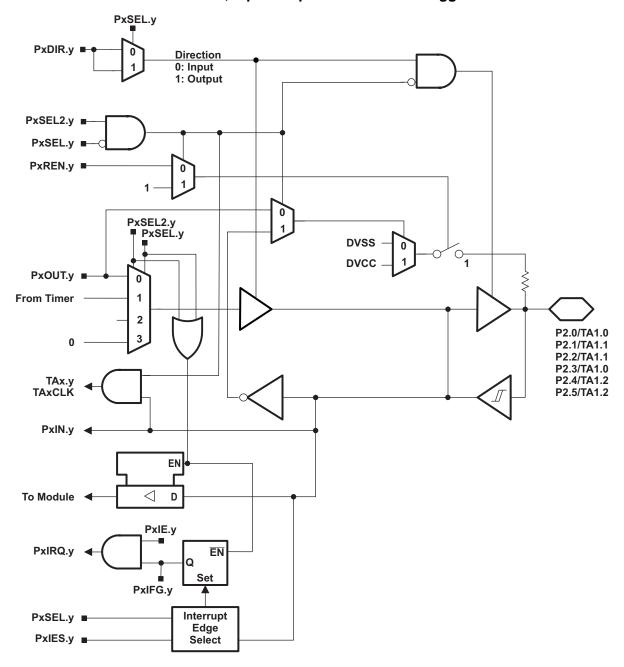




Table 20. Port P2 (P2.0 to P2.5) Pin Functions

PIN NAME		FUNCTION	CONTR	ROL BITS / SIGI	NALS ⁽¹⁾
(P2.x)	х	FUNCTION	P2DIR.x	P2SEL.x	P2SEL2.x
P2.0/		P2.x (I/O)	I: 0; O: 1	0	0
TA1.0/	0	Timer1_A3.CCI0A	0	1	0
	U	Timer1_A3.TA0	1	1	0
Pin Osc		Capacitive sensing	X	0	1
P2.1/		P2.x (I/O)	I: 0; O: 1	0	0
TA1.1/	4	Timer1_A3.CCl1A	0	1	0
	1	Timer1_A3.TA1	1	1	0
Pin Osc		Capacitive sensing	Х	0	1
P2.2/		P2.x (I/O)	I: 0; O: 1	0	0
TA1.1/	2	Timer1_A3.CCI1B	0	1	0
	2	Timer1_A3.TA1	1	1	0
Pin Osc		Capacitive sensing	Х	0	1
P2.3/		P2.x (I/O)	I: 0; O: 1	0	0
TA1.0/	3	Timer1_A3.CCI0B	0	1	0
	3	Timer1_A3.TA0	1	1	0
Pin Osc		Capacitive sensing	Х	0	1
P2.4/		P2.x (I/O)	I: 0; O: 1	0	0
TA1.2/	4	Timer1_A3.CCI2A	0	1	0
	4	Timer1_A3.TA2	1	1	0
Pin Osc		Capacitive sensing	X	0	1
P2.5/		P2.x (I/O)	I: 0; O: 1	0	0
TA1.2/	5	Timer1_A3.CCl2B	0	1	0
	5	Timer1_A3.TA2	1	1	0
Pin Osc		Capacitive sensing	Х	0	1

⁽¹⁾ X = don't care



Port P2 Pin Schematic: P2.6, Input/Output With Schmitt Trigger

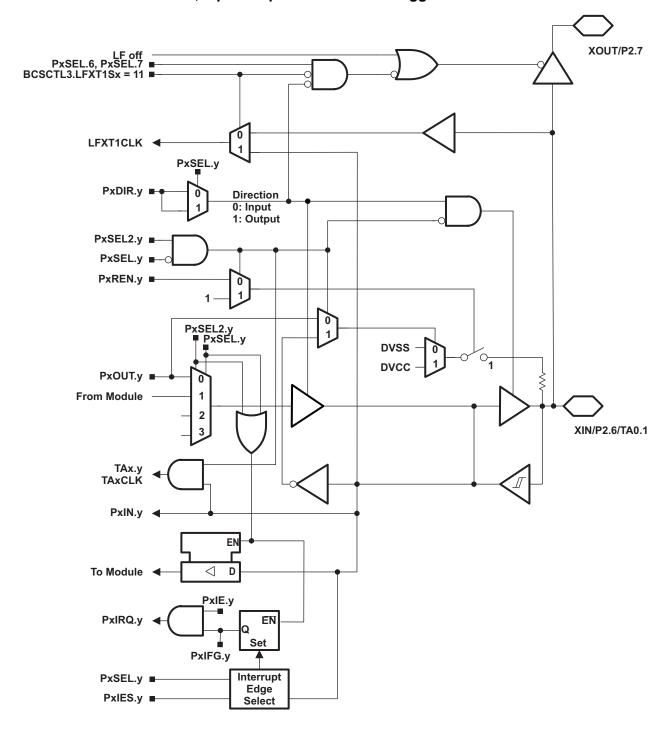




Table 21. Port P2 (P2.6) Pin Functions

PIN NAME		FUNCTION	CONTROL BITS / SIGNALS ⁽¹⁾				
(P2.x)	X		P2DIR.x	P2SEL.6 P2SEL.7	P2SEL2.6 P2SEL2.7		
XIN		XIN	0	1 1	0 0		
P2.6	6	P2.x (I/O)	I: 0; O: 1	X 0	0		
TA0.1	6	Timer0_A3.TA1	1	1 0	0 0		
Pin Osc		Capacitive sensing	Х	0 X	1 X		

(1) X = don't care



Port P2 Pin Schematic: P2.7, Input/Output With Schmitt Trigger

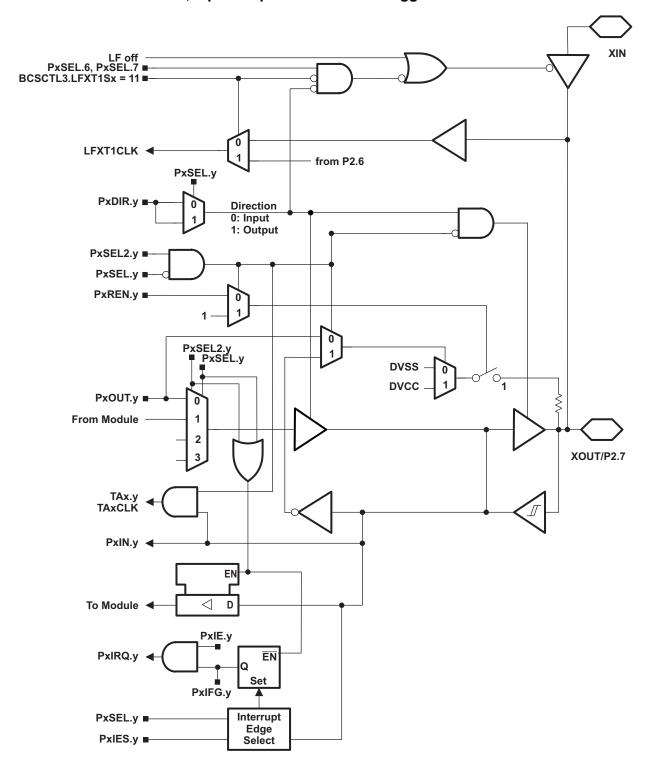




Table 22. Port P2 (P2.7) Pin Functions

PIN NAME (P2.x)		FUNCTION	CONTROL BITS / SIGNALS ⁽¹⁾				
	x		P2DIR.x	P2SEL.6 P2SEL.7	P2SEL2.6 P2SEL2.7		
XOUT/		XOUT	1	1 1	0 0		
P2.7/	7	P2.x (I/O)	I: 0; O: 1	0 X	0 0		
Pin Osc		Capacitive sensing	Х	0 X	1 X		

⁽¹⁾ X = don't care



Port P3 Pin Schematic: P3.0 to P3.7, Input/Output With Schmitt Trigger (RHB Package Only)

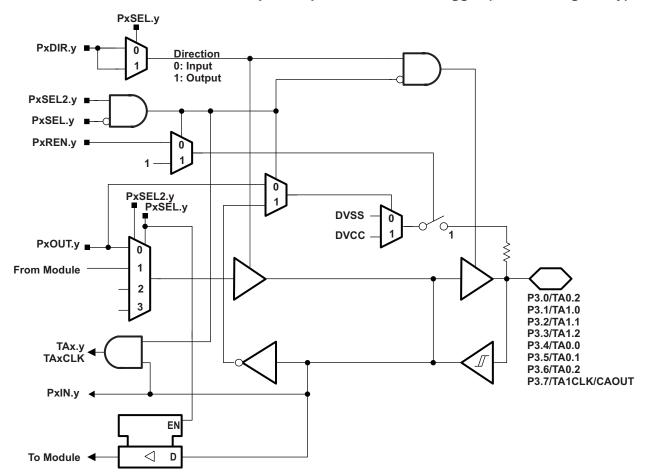




Table 23. Port P3 (P3.0 to P3.7) Pin Functions (RHB Package Only)

PIN NAME		FUNCTION	CONTR	CONTROL BITS / SIGNALS ⁽¹⁾						
(P3.x)	х	FUNCTION	P3DIR.x	P3SEL.x	P3SEL2.x					
P3.0/		P3.x (I/O)	I: 0; O: 1	0	0					
TA0.2/	0	Timer0_A3.CCI2A	0	1	0					
	0	Timer0_A3.TA2	1	1	0					
Pin Osc		Capacitive sensing	X	0	1					
P3.1/		P3.x (I/O)	I: 0; O: 1	0	0					
TA1.0/	1	Timer1_A3.TA0	1	1	0					
Pin Osc		Capacitive sensing	X	0	1					
P3.2/		P3.x (I/O)	I: 0; O: 1	0	0					
TA1.1/	2	Timer1_A3.TA1	1	1	0					
Pin Osc		Capacitive sensing	X	0	1					
P3.3/		P3.x (I/O)	I: 0; O: 1	0	0					
TA1.2/	3	Timer1_A3.TA2	1	1	0					
Pin Osc		Capacitive sensing	X	0	1					
P3.4/		P3.x (I/O)	I: 0; O: 1	0	0					
TA0.0/	4	Timer0_A3.TA0	1	1	0					
Pin Osc		Capacitive sensing	X	0	1					
P3.5/		P3.x (I/O)	I: 0; O: 1	0	0					
TA0.1/	5	Timer0_A3.TA1	1	1	0					
Pin Osc		Capacitive sensing	X	0	1					
P3.6/		P3.x (I/O)	I: 0; O: 1	0	0					
TA0.2/	6	Timer0_A3.TA2	1	1	0					
Pin Osc		Capacitive sensing	X	0	1					
P3.7/		P3.x (I/O)	I: 0; O: 1	0	0					
TA1CLK/	7	Timer1_A3.TACLK	0	1	0					
Pin Osc		Capacitive sensing	X	0	1					

⁽¹⁾ X = don't care



REVISION HISTORY

REVISION	DESCRIPTION
SLAS734	Production Data release
SLAS734A	Corrections to Control Bits / Signals column in Table 18 Corrections to Pin Name and Function columns in Table 23
SLAS734B	Changed Storage temperature range limit in Absolute Maximum Ratings Added BSL functions to P1.1 and P1.5 in Table 2 Port P1 Pin Schematic, corrected pin name
SLAS734C	Changed T _{stg} , Programmed device, to -55°C to 150°C in Absolute Maximum Ratings. Changed TAG_ADC10_1 value to 0x10 in Table 10.
SLAS734D	Added AVCC (RHB package only, pin 29) to Table 2 Terminal Functions. Correct typo in P3.7/TA1CLK description in Table 2. Corrected pin number for PW28 Input and Output columns in Table 13. Changed all port schematics (added buffer after PxOUT.y mux) in Port Schematics.
SLAS734E	Corrected all Timer_A register names (changed to TA0 or TA1 as appropriate) in Table 14. Changed note (1) in Output Frequency, Ports Px. Fixed typo in name of UCA0SIMO (pin 4) in N20 pinout drawing. Recommended Operating Conditions, Added test conditions for typical values. Pin-Oscillator Frequency – Ports Px, Changed resistor values in note (1). POR, BOR, Added note (2).
SLAS734F	Throughout, Changed all variations of touch sense (1) to capacitive touch.

⁽¹⁾ TouchSense is a trademark of Immersion Corporation.





30-Apr-2015

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
MSP430G2203IN20	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	M430G2203	Samples
MSP430G2203IPW20	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2203	Samples
MSP430G2203IPW20R	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2203	Samples
MSP430G2203IPW28	ACTIVE	TSSOP	PW	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2203	Samples
MSP430G2203IPW28R	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2203	Samples
MSP430G2203IRHB32R	ACTIVE	VQFN	RHB	32	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	MSP430 G2203	Samples
MSP430G2233IN20	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	M430G2233	Samples
MSP430G2233IPW20	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2233	Samples
MSP430G2233IPW20R	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2233	Samples
MSP430G2233IPW28	ACTIVE	TSSOP	PW	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2233	Samples
MSP430G2233IPW28R	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2233	Samples
MSP430G2233IRHB32R	ACTIVE	VQFN	RHB	32	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	MSP430 G2233	Samples
MSP430G2233IRHB32T	ACTIVE	VQFN	RHB	32	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	MSP430 G2233	Samples
MSP430G2303IN20	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	M430G2303	Samples
MSP430G2303IPW20	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2303	Samples
MSP430G2303IPW20R	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2303	Sample
MSP430G2303IPW28	ACTIVE	TSSOP	PW	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2303	Samples



30-Apr-2015

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Sampl
MSP430G2303IPW28R	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2303	Sampl
MSP430G2303IRHB32R	ACTIVE	VQFN	RHB	32	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	MSP430 G2303	Sampl
MSP430G2303IRHB32T	ACTIVE	VQFN	RHB	32	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	MSP430 G2303	Samp
MSP430G2333IN20	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	M430G2333	Samp
MSP430G2333IPW20	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2333	Samp
MSP430G2333IPW20R	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2333	Samp
MSP430G2333IPW28	ACTIVE	TSSOP	PW	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2333	Samp
MSP430G2333IPW28R	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2333	Samp
MSP430G2333IRHB32R	ACTIVE	VQFN	RHB	32	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	MSP430 G2333	Samp
MSP430G2333IRHB32T	ACTIVE	VQFN	RHB	32	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	MSP430 G2333	Samp
MSP430G2403IN20	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	M430G2403	Samp
MSP430G2403IPW20	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2403	Samp
MSP430G2403IPW20R	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2403	Samp
MSP430G2403IPW28	ACTIVE	TSSOP	PW	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2403	Samp
MSP430G2403IPW28R	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2403	Samp
MSP430G2403IRHB32R	ACTIVE	VQFN	RHB	32	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	MSP430 G2403	Samp
MSP430G2403IRHB32T	ACTIVE	VQFN	RHB	32	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	MSP430 G2403	Samp
MSP430G2433IN20	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	M430G2433	Samp





30-Apr-2015

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
MSP430G2433IPW20	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2433	Samples
MSP430G2433IPW20R	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2433	Samples
MSP430G2433IPW28	ACTIVE	TSSOP	PW	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2433	Samples
MSP430G2433IPW28R	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2433	Samples
MSP430G2433IRHB32R	ACTIVE	VQFN	RHB	32	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	MSP430 G2433	Samples
MSP430G2433IRHB32T	ACTIVE	VQFN	RHB	32	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	MSP430 G2433	Samples
MSP430G2533IN20	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	M430G2533	Samples
MSP430G2533IPW20	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2533	Samples
MSP430G2533IPW20R	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2533	Samples
MSP430G2533IPW28	ACTIVE	TSSOP	PW	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2533	Samples
MSP430G2533IPW28R	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	430G2533	Samples
MSP430G2533IRHB32R	ACTIVE	VQFN	RHB	32	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	MSP430 G2533	Samples
MSP430G2533IRHB32T	ACTIVE	VQFN	RHB	32	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	MSP430 G2533	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

30-Apr-2015

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF MSP430G2333:

Automotive: MSP430G2333-Q1

NOTE: Qualified Version Definitions:

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

www.ti.com 22-Jul-2015

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



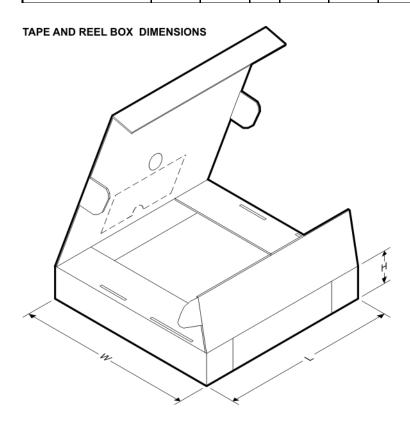
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MSP430G2203IPW20R	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
MSP430G2203IPW20R	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
MSP430G2203IPW28R	TSSOP	PW	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1
MSP430G2203IPW28R	TSSOP	PW	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1
MSP430G2203IRHB32R	VQFN	RHB	32	3000	330.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
MSP430G2233IPW20R	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
MSP430G2233IPW20R	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
MSP430G2233IPW28R	TSSOP	PW	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1
MSP430G2233IPW28R	TSSOP	PW	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1
MSP430G2233IRHB32R	VQFN	RHB	32	3000	330.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
MSP430G2233IRHB32T	VQFN	RHB	32	250	180.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
MSP430G2303IPW20R	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
MSP430G2303IPW28R	TSSOP	PW	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1
MSP430G2303IPW28R	TSSOP	PW	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1
MSP430G2303IRHB32R	VQFN	RHB	32	3000	330.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
MSP430G2303IRHB32T	VQFN	RHB	32	250	180.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
MSP430G2333IPW20R	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
MSP430G2333IPW28R	TSSOP	PW	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1

PACKAGE MATERIALS INFORMATION

www.ti.com 22-Jul-2015

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MSP430G2333IRHB32R	VQFN	RHB	32	3000	330.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
MSP430G2333IRHB32T	VQFN	RHB	32	250	180.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
MSP430G2403IPW20R	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
MSP430G2403IPW28R	TSSOP	PW	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1
MSP430G2403IRHB32R	VQFN	RHB	32	3000	330.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
MSP430G2403IRHB32T	VQFN	RHB	32	250	180.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
MSP430G2433IPW20R	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
MSP430G2433IPW28R	TSSOP	PW	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1
MSP430G2433IRHB32R	VQFN	RHB	32	3000	330.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
MSP430G2433IRHB32T	VQFN	RHB	32	250	180.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
MSP430G2533IPW20R	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
MSP430G2533IPW28R	TSSOP	PW	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1
MSP430G2533IPW28R	TSSOP	PW	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1
MSP430G2533IRHB32R	VQFN	RHB	32	3000	330.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
MSP430G2533IRHB32R	VQFN	RHB	32	3000	330.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
MSP430G2533IRHB32T	VQFN	RHB	32	250	180.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
MSP430G2533IRHB32T	VQFN	RHB	32	250	180.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2



^{*}All dimensions are nominal



PACKAGE MATERIALS INFORMATION

www.ti.com 22-Jul-2015

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MSP430G2203IPW20R	TSSOP	PW	20	2000	367.0	367.0	38.0
MSP430G2203IPW20R	TSSOP	PW	20	2000	367.0	367.0	38.0
MSP430G2203IPW28R	TSSOP	PW	28	2000	367.0	367.0	38.0
MSP430G2203IPW28R	TSSOP	PW	28	2000	367.0	367.0	38.0
MSP430G2203IRHB32R	VQFN	RHB	32	3000	367.0	367.0	35.0
MSP430G2233IPW20R	TSSOP	PW	20	2000	367.0	367.0	38.0
MSP430G2233IPW20R	TSSOP	PW	20	2000	367.0	367.0	38.0
MSP430G2233IPW28R	TSSOP	PW	28	2000	367.0	367.0	38.0
MSP430G2233IPW28R	TSSOP	PW	28	2000	367.0	367.0	38.0
MSP430G2233IRHB32R	VQFN	RHB	32	3000	367.0	367.0	35.0
MSP430G2233IRHB32T	VQFN	RHB	32	250	210.0	185.0	35.0
MSP430G2303IPW20R	TSSOP	PW	20	2000	367.0	367.0	38.0
MSP430G2303IPW28R	TSSOP	PW	28	2000	367.0	367.0	38.0
MSP430G2303IPW28R	TSSOP	PW	28	2000	367.0	367.0	38.0
MSP430G2303IRHB32R	VQFN	RHB	32	3000	367.0	367.0	35.0
MSP430G2303IRHB32T	VQFN	RHB	32	250	210.0	185.0	35.0
MSP430G2333IPW20R	TSSOP	PW	20	2000	367.0	367.0	38.0
MSP430G2333IPW28R	TSSOP	PW	28	2000	367.0	367.0	38.0
MSP430G2333IRHB32R	VQFN	RHB	32	3000	367.0	367.0	35.0
MSP430G2333IRHB32T	VQFN	RHB	32	250	210.0	185.0	35.0
MSP430G2403IPW20R	TSSOP	PW	20	2000	367.0	367.0	38.0
MSP430G2403IPW28R	TSSOP	PW	28	2000	367.0	367.0	38.0
MSP430G2403IRHB32R	VQFN	RHB	32	3000	367.0	367.0	35.0
MSP430G2403IRHB32T	VQFN	RHB	32	250	210.0	185.0	35.0
MSP430G2433IPW20R	TSSOP	PW	20	2000	367.0	367.0	38.0
MSP430G2433IPW28R	TSSOP	PW	28	2000	367.0	367.0	38.0
MSP430G2433IRHB32R	VQFN	RHB	32	3000	367.0	367.0	35.0
MSP430G2433IRHB32T	VQFN	RHB	32	250	210.0	185.0	35.0
MSP430G2533IPW20R	TSSOP	PW	20	2000	367.0	367.0	38.0
MSP430G2533IPW28R	TSSOP	PW	28	2000	367.0	367.0	38.0
MSP430G2533IPW28R	TSSOP	PW	28	2000	367.0	367.0	38.0
MSP430G2533IRHB32R	VQFN	RHB	32	3000	367.0	367.0	35.0
MSP430G2533IRHB32R	VQFN	RHB	32	3000	367.0	367.0	35.0
MSP430G2533IRHB32T	VQFN	RHB	32	250	210.0	185.0	35.0
MSP430G2533IRHB32T	VQFN	RHB	32	250	210.0	185.0	35.0

PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G28)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G28)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G28)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



RHB (S-PVQFN-N32)

PLASTIC QUAD FLATPACK NO-LEAD



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) Package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F. Falls within JEDEC MO-220.



RHB (S-PVQFN-N32)

PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



NOTE: A. All linear dimensions are in millimeters



RHB (S-PVQFN-N32)

PLASTIC QUAD FLATPACK NO-LEAD



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com www.ti.com.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- E. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for any larger diameter vias placed in the thermal pad.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive **Amplifiers** amplifier.ti.com Communications and Telecom www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers **DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps DSP dsp.ti.com **Energy and Lighting** www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical Logic Security www.ti.com/security logic.ti.com

Power Mgmt power.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Microcontrollers microcontroller.ti.com Video and Imaging www.ti.com/video

RFID www.ti-rfid.com

OMAP Applications Processors www.ti.com/omap TI E2E Community e2e.ti.com

Wireless Connectivity www.ti.com/wirelessconnectivity